

YTM32B1ME0x Data Sheet

Support: YTM32B1ME05G0MLQT, YTM32B1ME05G0MLQCT, YTM32B1ME05G0MLLT,
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1 Features Summary

- AEC-Q100 qualified
- ASIL B compliant
- RoHS compliant
- 32-bit Cortex-M33 with FPU and DSP, up to 120 MHz
- Up to 1 MB Program Flash memory and 256 KB Data Flash with ECC support
- Up to 128 KB SRAM
 - Support ECC feature
 - Two 16 KB SRAM blocks which support data retention in Powerdown mode
- 32 bytes register file which supports data retention in Powerdown mode
- Provide multiple clock sources including:
 - 96 MHz Fast Internal RC Oscillator(FIRC)
 - 4~40 MHz Fast Crystal Oscillator(FXOSC)
 - Up to 120 MHz Phase-Locked Loop(PLL)
 - 12 MHz Slow Internal RC Oscillator(SIRC)
 - 32.768 KHz Slow Crystal Oscillator(SXOSC)
- Power Control Unit (PCU) with internal regulators capable of supporting multiple power modes including:
 - Active
 - Sleep
 - Deepsleep
 - Standby
 - Powerdown
- Support up to 32 WKU pins to wake up from Powerdown mode
- 16 DMA channels with up to 70 hardware trigger sources
- Human-machine interface
 - Up to 126 general-purpose input/output (GPIO)
 - External interrupt
- Analog modules providing precision mixed-signal capabilities, including:
 - Two 12-bit, 2Msps SAR ADCs, up to 48 external channels and 7 internal channels
 - On-chip Analog Comparator (ACMP) with 8-bit DAC, up to 8 channels
- Support temperature sensor
- Timers
 - One Timer (TMR)
 - One 4-channel Periodic Timer (pTMR)
 - One Low Power Timer (lpTMR)
 - Six Enhanced Timer (eTMR)
 - One Real-Time Clock (RTC)
 - Two Programmable Trigger Unit (PTU)
- Serial communication interfaces
 - Six FlexCAN modules with FD
 - Six LINFlexD modules
 - Six SPI modules
 - Three I2C modules
- I/O supporting 2.97 V ~ 5.5 V supply
- Wide operating voltage ranges (2.97 ~ 5.5 V) with fully functional flash memory program/erase/read operations
- Temperature range:
 - Ambient operating temperature: -40 °C ~ 125 °C
 - Junction operating temperature: -40 °C ~ 150 °C
- Security and Safety features are supported as follows:
 - Cyclic Redundancy Checker (CRC)
 - Hardware Cryptography Unit (HCU) which supports AES/SM4/SHA
 - True Random Number Generator (TRNG)
 - Clock Monitor Unit (CMU)
 - Watchdog (WDG)
 - External watchdog (EWDG)
 - MPU for dynamic task protection (16 regions)
 - Peripheral Protection Unit (PPU)
 - Interrupt Monitor (INTM)
 - ECC Management Unit (EMU)
- Debug functionality
 - Joint Test Action Group (IEEE 1149.1 standard)
 - Serial Wire Debug (SWD)
- Package options
 - 144-pin LQFP
 - 100-pin LQFP
 - 64-pin LQFP

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2 Overview

YTM32B1ME0x series provide the highly scalable portfolio of ARM® Cortex®-M33 MCUs in the automotive industry with the Arm Cortex-M33 core at higher frequency, more memory, ASIL-B rating and advanced security module. With 2.97 ~ 5.5 V supply and focus on exceptional EMC/ESD robustness, YTM32B1ME0x series devices are well suited to a wide range of applications in electrical harsh environments, and are optimized for cost-sensitive applications offering low pin-count option.

The YTM32B1ME0x series offer a broad range of memory, peripherals and package options. They share common peripherals and pin counts allowing developers to migrate easily within an MCU family or among the MCU families to take advantage of more memory or feature integration. This scalability allows developers to standardize on the YTM32B1ME0x series for their end product platforms, maximizing hardware and software reuse and reducing time-to-market.

3 Block Diagram

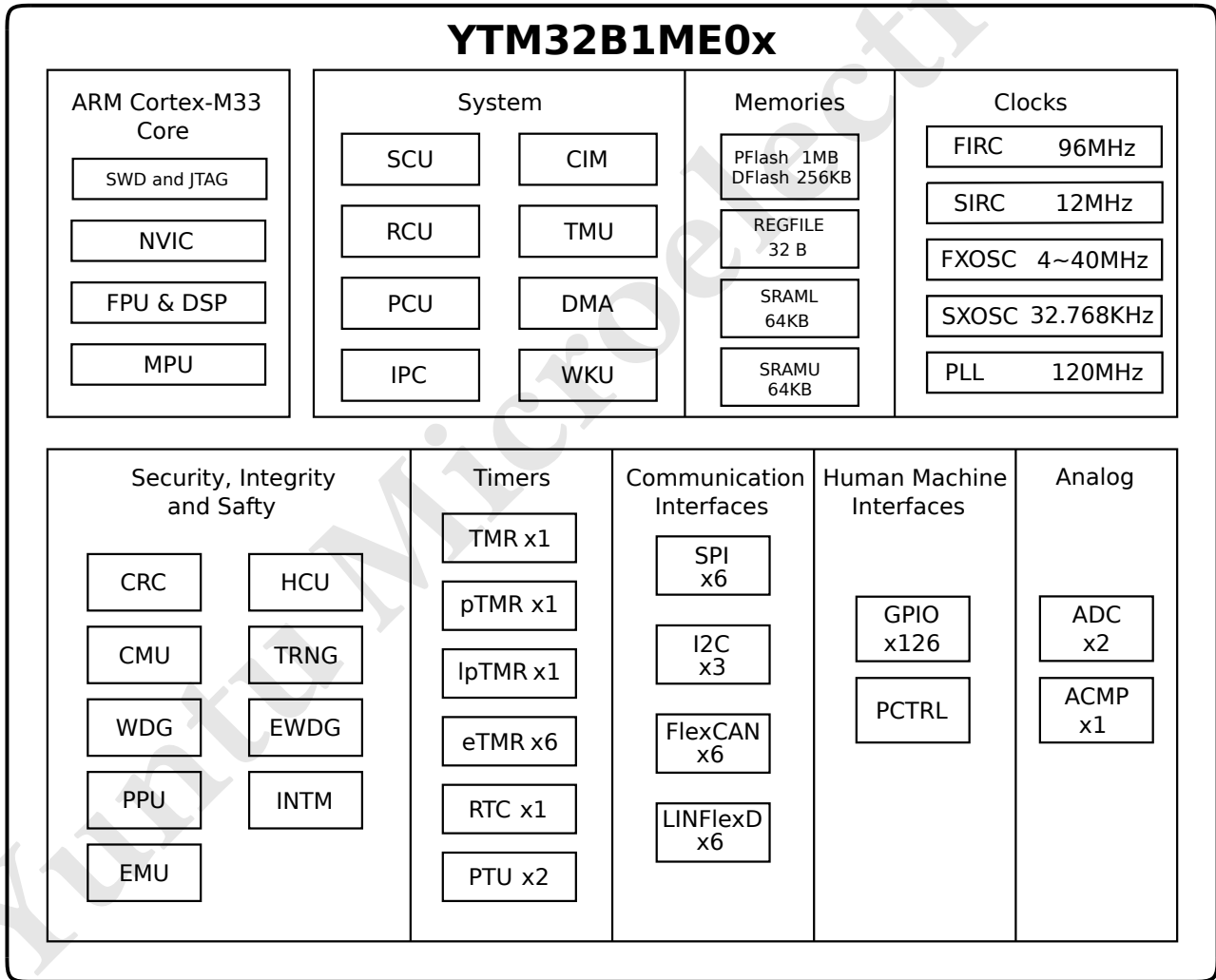


Figure 1: YTM32B1ME0x Block Diagram

4 Features

The following sections describe the high-level module features for YTM32B1ME0x device.

4.1 Core Modules

4.1.1 ARM Cortex-M33

- ARM Cortex M33 core running up to 120 MHz
- ARMv8-M MPU for dynamic task protection (16 regions)
- Single cycle 32 x 32 bits multiply
- 3-stage pipeline, thumb-2 technology
- Digital Signal Processor (DSP)
- Single Precision Floating Point Unit (FPv5), IEEE 754 compliant
- Support for the instruction trace option:
 - Embedded Trace Macrocell (ETM)
- Binary compatible instruction set with the ARM Cortex M4/M7

4.1.2 Nested Vector Interrupt Controller (NVIC)

- 8 priority levels
- Up to 192 interrupt sources
- Includes a single non-maskable interrupt

4.1.3 Debug Controller

- 2-pin serial wire debug (SWD) provides external debugger interface
- Support JTAG port (IEEE 1149.1 standard)
- Support ITM(Instruction Trace Macrocell): S/W Instrumentation Messaging + Simple Data Trace Messaging + watch points Messaging
- Support ETM(Embedded Trace Macrocell): Used for instruction trace
- Support DWT(Data and Address Watch points): 8 flash breakpoints and 4 data watch points

4.2 System Modules

4.2.1 System Clock Unit (SCU)

- Fast Internal RC Oscillator(FIRC)
 - Up to 96 MHz
 - Default system boot clock source
 - Support trim for temperature and process
 - Can be selected as PLL reference clock
- Slow Internal RC Oscillator(SIRC)
 - Can be selected as system clock source
 - Always on unless it is forced to be disable in standby mode
 - Support trim for temperature and process
- Fast Crystal Oscillator(FXOSC)
 - Support 4~40MHz crystal
 - Can be selected as PLL reference clock
 - Can be selected as system clock source
 - Support bypass mode
- Slow Crystal Oscillator(SXOSC)
 - 32.768 KHz real time oscillator
 - Can't be selected as system clock
 - Provides accurate clock to watchdog(WDG) and real time clock(RTC)

- Phase-Locked Loop(PLL)
 - Up to 120 MHz
 - Contains voltage-controlled oscillator(VCO)
 - Support selectable reference clock
 - Contain Frequency lock detector
 - Can be selected as system clock source
- Clock Monitor Unit(CMU)
 - SCU contains 4 CMU blocks
 - CMU monitors slow bus clock, FIRC clock, FXOSC clock and PLL clock
 - FXOSC or SIRC clock can be selected as reference clock of CMU
 - CMU can detect frequency out of range, loss of checked clock and loss of reference clock
- SCU provides glitch free switcher to select system clock source
- SCU provides system clock dividers to generate fast bus clock, slow bus clock and core clock

4.2.2 Power Control Unit (PCU)

- Combination of internal and external voltage regulator options, offering a variety of power modes
- Active POR providing brown-out detect
- Low voltage reset for all system relevant power domains (LVR)
- High voltage detect (HVD) as indication for software.

4.2.3 Reset Control Unit (RCU)

- Record the reset sources of most recent resets
- Configurable filter for reset pin
- Reset pin filter can work at both active and low power mode

4.2.4 IP Controller (IPC)

- Peripheral Bus clock enable
- IPC clock source selection as follow
 - PLL 120MHz
 - FIRC 96MHz
 - SIRC 12MHz
 - FXOSC 4~40MHz
 - SXOSC 32.768KHz
- IPC clock divide values from 1 to 16
- Peripheral software reset

4.2.5 Wakeup Unit (WKU)

- Support for up to 32 external input pins and up to 3 internal modules with individual enable bits for MCU interrupt from Powerdown mode.
- Input sources may be external pins or from internal modules capable of running in Powerdown mode.
- External input pins programmable for falling-edge, rising-edge, or any-edge detection.
- Support to enable external input pin and filter detection in Powerdown mode.
- Optional digital filters provided to qualify an external pin detect. Note that when the SIRC and SXOSC clock is disabled, filters are disabled and bypassed.

4.2.6 Direct Memory Access (DMA)

- All address range data transfer from source to destination
- Support separate source/destination data size configuration
 - Word(32-bit), half word(16-bit), byte(8-bit) transfer size
- Support separate source/destination address offset configuration
 - Address increase/decrease/keep selectable
- Up to 16 DMA channels
 - Fix priority and round-robin arbitration
 - Support channel to channel link
- Software/Hardware/Link trigger
- Up to 128 peripheral hardware triggers
- Internal data fifo for data transfer
- Support update DMA transfer information from system memory after transfer complete
- Support data transfer loop and trigger loop

4.2.7 Trigger Multiplex Unit (TMU)

- Allow software to select the trigger sources for peripherals as trigger sources

4.2.8 Chip Integration Module (CIM)

- System function configuration
- ADC/ACMP trigger synchronize selection
- Software trigger generate
- eTMR external clock and fault selection
- FPU interrupt enable
- System unique device identification (UID)
- Flash memory and system RAM size configuration
- Package configuration
- FlexCAN FD feature configuration

4.3 Memories

4.3.1 Embedded Flash Module (EFM)

- up to 1024 KB Program Flash(PFlash)
 - it separates 2 blocks, each block includes 256 sectors, each sector is 2 KB
 - support ECC
 - support OTA
- up to 256 KB Data Flash(DFlash)
 - it includes 256 sectors, each sector is 1 KB
 - support ECC
- 3K bytes NVR Array with ECC includes 3 sectors, each sector is 1K bytes
- Protection scheme against accidental program or erase operations
- Optional interrupt on command completion and status update

4.3.2 Register File (REGFILE)

- Retain value during Powerdown mode.
- Access through APB bus.

4.3.3 On-chip SRAM

- 64 KB TCML and 64 KB TCMU
- Support ECC feature
- Two regions of 16KB SRAM which supports data retention in Powerdown mode

4.4 Analog

4.4.1 Analog-to-Digital Converter (ADC)

- Contain two ADC instances
 - ADC0 supports up to 24 external analog input channels, and 7 internal channels
 - ADC1 supports up to 24 external analog input channels
- Support 12-bit, 10-bit, 8-bit, and 6-bit single-ended configurable resolution
- Up to 2Msps for 12-bit resolution conversion performance
- Support DMA and conversion result FIFO with watermark
- Support multiple conversion modes
 - Single mode
 - Continuous mode
 - Discontinuous mode
- Support software/hardware trigger for ADC start conversion
- Support two power saving modes
 - Wait mode: prevent ADC overrun when FIFO is full
 - Auto off mode: automatic control ADC power off
- Support watchdog for conversion result monitoring
- Support interrupt generate
 - Ready for conversion
 - End of sampling
 - End of conversion
 - End of sequence conversion
 - Overrun event
 - Watchdog event
- Support work and wake up when the chip under low power mode

4.4.2 Analog Comparator (ACMP)

- Up to 8 channels
- Operational over the entire supply range
- Inputs may range from rail to rail
- Programmable hysteresis control
- Selectable inversion on comparator output
- Function mode:
 - Common mode
 - Sample mode
 - Window mode
 - Continuous mode
 - * one-shot mode
 - * loop mode
- All channels can be used to execute automatic comparison
- Support digital filter, the filter can be bypassed
- Two software selectable performance levels

- Shorter propagation delay at the expense of higher power
- Low power with longer propagation delay
- Functional in all power mode
- Support independent 8-bit DAC output to the comparator
- Support several interrupts
 - For common/sample/window mode
 - Generate interrupt on rising-edge, falling-edge or both edges of the comparator output
 - For continuous mode
 - Generate interrupt when the comparison results don't match with expectations
- Interrupt can be generated without any clock in common mode
- A comparison event can be selected to trigger DMA transfer

4.5 Timers

4.5.1 Timer (TMR)

- One 32-bit count-up timer with an 8-bit prescaler
- Four 32-bit compare channels
- An independent interrupt source for each channel
- Ability to stop the timer in debug mode

4.5.2 Periodic Timer (pTMR)

- Timers can generate interrupts, and each channel can generate independent interrupt request
- Four channels of 32bit timers, each timer has independent timeout periods
- Ability to stop in debug mode
- Support chain mode to connect multiple timer to a longer timer

4.5.3 Low Power Timer (lpTMR)

- 16-bit time counter or pulse counter with compare
- Optional interrupt can generate asynchronous wakeup from any low-power mode
- Hardware trigger output
- Counter supports free-running mode or reset on compare
- Configurable clock source for prescaler/glitch filter
- Configurable input source for pulse counter
 - Rising-edge or falling-edge

4.5.4 Enhanced Timer (eTMR)

This chip contains 6 eTMRs (eTMR0, eTMR1, eTMR2, eTMR3, eTMR4, eTMR5), their features are divided into common features and individual features.

The common features of all eTMRs are listed below:

- Configurable initial and final counter values
- Contain 8 channels
- Support two clock sources
 - Bus clock
 - External clock
- Support 7-bits clock prescaler

- Support three channel modes
 - PWM mode
 - * Independent mode for each channel
 - * Complementary mode for each pair of channels
 - All channels support independent deadtime insertion
 - * Support dithering
 - * Channel output control (initialization, software control, mask control, double switch control, fault control)
 - Support 4 fault input sources
 - Support fault input from TMU or pad
 - Support fault input polarity control
 - Support fault input filter
 - Support fault input stretch
 - Support fault event generated by combinational logic
 - * Relevant registers have buffer registers and support loading mechanism
 - Output Compare mode
 - * The output can be configured to set, clear or toggle on match point
 - Input Capture mode
 - * Support rising edges, falling edges or dual edges capture
 - * Support input filter with a prescaler
 - * Support capture test mode
 - * Support pulse width measure
- Support generating triggers
 - Output triggers with adjustable pulse width on match point
 - Output pulse with adjustable width by PWM
- Polarity control is available for each channel
- Support GTB (Global Time Base)
- Support several interrupts
 - Channel interrupt (capture interrupt and compare interrupt)
 - Counter overflow interrupt
 - Fault event interrupt
- Support DMA
- Support counter running under debug mode

The individual features are listed below:

- Counter
 - eTMR3 has a 32-bit counter
 - Other eTMRs have a 16-bit counter
- eTMR1 and eTMR2 support quadrature decoder mode
 - Contain a independent 16-bit counter with a clock prescaler
 - Support 4 up-down counting modes
 - Support phase A and phase B input filter
 - Support quadrature decoder counter overflow interrupt
- eTMR0 and eTMR3 support modulated output
- eTMR2 supports hall sensor input
- eTMR1 and eTMR2 support input from ACMP

4.5.5 Real-Time Clock (RTC)

- 32-bit seconds counter with overflow flag and optional interrupt

- Configurable 32-bit alarm
- 16-bit prescaler with compensation that can correct errors
- Register write protection
- Configurable 1, 2, 4, 8, 16, 32, 64 or 128 Hz square wave output with optional interrupt
- Lock support of register access for control and alarm register

4.5.6 Programmable Trigger Unit (PTU)

- 8 Configurable PTU channels for ADC hardware trigger
- Each trigger output can be enabled/disabled independently
- Configurable delay per pre-trigger output
- Support Bypass of pre-trigger delay
- Support software trigger source
- Support Continuous Mode
- Optional interrupt of counter and sequence error
- Support pulse output as ACMP's sample window

4.6 Security, Integrity and Safety

4.6.1 Cyclic Redundancy Check (CRC)

- The following CRC polynomials are implemented:
 - CRC4 (CRC-ITU):
$$X^4 + X + 1$$
 - CRC16 (CRC-CCITT):
$$X^{16} + X^{12} + X^5 + 1$$
 - CRC32 (CRC-ethernet):
$$X^{32} + X^{26} + X^{23} + X^{22} + X^{16} + X^{12} + X^{11} + X^{10} + X^8 + X^7 + X^5 + X^4 + X^2 + X + 1$$
- Programmable initial seed
- Optional bit-swap in one byte is available for input data
- Optional bit-swap in one word is available for output data
- Optional bit-inversion is available for output data
- 8/16/32-bit access for CRC input data

4.6.2 Hardware Cryptography Unit (HCU)

- Support 128-, 192- and 256-bit key length
- Support both encryption and decryption
- Support secure hardware key and flexible software key
- Support several algorithm engines
 - AES (ECB, CBC, CTR, CCM, CMAC)
 - SM4 (ECB)
 - SHA (SHA-256, SHA-384)
- All data is in big-endian format
- Support 1-, 8- and 16-bit data swap
- Size of input/output FIFO is up to 32*32 bits
- The input FIFO data is processed in 128 bits
- Support DMA transport between chip memory and input/output FIFO
- Support several interrupts
 - Operation done interrupt
 - Input FIFO empty interrupt

- Output FIFO full interrupt
- Input FIFO overflow interrupt
- Output FIFO underflow interrupt
- Input/output FIFO watermark interrupt
- Clock gating strategy is applied for engine core when input/output FIFO is not ready

4.6.3 True Random Number Generator (TRNG)

- Generate a 256-bit entropy
- Monobit limit test
- Long run test
- 1 ring OSC with clock checker
- 3 interrupt source

4.6.4 Watchdog (WDG)

- 32-bit countdown timer
- Functional clock can be selected from SIRC and SXOSC
- Support regular or window servicing mode
- Support reset request or interrupt for the first timeout
- Hard and soft configuration lock bits
- Support fixed key for dog feeding

4.6.5 External Watchdog (EWDG)

- Selectable clock sources from SIRC_CLK or SXOSC_CLK
- Programmable window and fixed service code for refresh the EWDG
- One input port to collect external safety critical signal input
- One output port to put the external circuits into safe mode

4.6.6 ECC Management Unit (EMU)

- Two channels to ECC injection and report: TCML and TCMU
- Two-stage enable mechanism to ECC injection and ECC report
- Location and correction or non-correction error can be injected
- ECC error interrupt under each enable register's control
- The last error information can be recorded, including address and syndrome

4.7 Communication Interfaces

4.7.1 Flexible Controller Area Network (FlexCAN)

- Full implementation of the CAN FD protocol and CAN Specification 2.0, Part B
 - Standard data frames
 - Extended data frames
 - Zero to sixty-four bytes data length
 - Programmable bit rate
 - Content-related addressing
- Compliant with the ISO 11898-1 standard
- Silicon-proven implementation passing ISO 16845-1:2016 CAN conformance tests
- Flexible mailboxes configurable to store 0 to 8, 16, 32, or 64 bytes data length

- Each mailbox configurable as receive or transmit, all supporting standard and extended messages
- Individual Rx Mask registers per mailbox
- Full-featured Legacy Rx FIFO with storage capacity for up to 6 CAN frames and automatic internal pointer handling with DMA support
- Full-featured Enhanced Rx FIFO with storage capacity for up to 32 CAN FD frames and automatic internal pointer handling with DMA support
- Transmission abort capability
- Flexible message buffers, totaling 128 message buffers of 8 bytes data length each, configurable as Rx or Tx
- Programmable clock source to the CAN Protocol Engine, either peripheral clock or oscillator clock
- RAM not used by reception or transmission structures can be used as general purpose RAM space
- Listen-Only mode capability
- Programmable Loop-Back mode supporting self-test operation
- Programmable transmission priority scheme: lowest ID, lowest buffer number, or highest priority
- Time stamp based on 16-bit free-running timer, with an optional external time tick or high-resolution 32-bit on-chip timer
- Global network time, synchronized by a specific message
- Maskable interrupts
- Independence from the transmission medium (an external transceiver is assumed)
- Short latency time due to an arbitration scheme for high-priority messages
- Low-Power modes, with programmable Wake-Up on bus activity or matching with received frames (Pretended Networking)
- Transceiver Delay Compensation feature when transmitting CAN FD messages at faster data rates
- Remote request frames may be managed automatically or by software
- CAN bit time settings and configuration bits can only be written in Freeze mode
- Tx mailbox status (lowest priority buffer or empty buffer)
- Identifier Acceptance Filter Hit Indicator (IDHIT) register for received frames
- SYNCH bit available in Error in Status 1 register to indicate that the FlexCAN is synchronous with CAN bus
- CRC status for transmitted message
- Legacy Rx FIFO Global Mask register
- Selectable priority between mailboxes and Rx FIFO during matching process
- Powerful Legacy Rx FIFO ID filtering, capable of matching incoming IDs against either 128 extended, 256 standard, or 512 partial (8 bit) IDs, with up to 32 ID Filter Table elements
- Powerful Enhanced Rx FIFO ID filtering, capable of matching incoming IDs against either 64 extended or 128 standard ID filter elements with three filtering schemes: mask + filter, range, and two filters without mask
- 100% backward compatibility with previous FlexCAN version
- Supports detection and correction of errors in memory read accesses. Each byte of FlexCAN memory is associated to 5 parity bits. The error correction mechanism ensures that in this 13-bit word, errors in one bit can be corrected (correctable errors) and errors in 2 bits can be detected but not corrected (non-correctable errors).
- Supports Pretended Networking functionality in Low-Power modes: Doze mode, Deepsleep mode

4.7.2 Local Interconnect Network (LINFlexD)

- LINFlexD common features in both LIN and UART mode:
 - Support asynchronous functional clock from IPC
 - Fractional baud rate generator
 - Three operating modes for power saving and configuration registers lock
 - * Initialization
 - * Normal

- * Sleep
- Test mode: Loop Back
- Maskable interrupts
- LIN mode features include:
 - Support edge wakeup under low power mode
 - Support for LIN protocol versions 1.3, 2.0, 2.1 and 2.2
 - Bit rates up to 20 Kbit/s (LIN protocol)
 - Master/slave modes
 - Classic and enhanced checksum calculation and check
 - Single 8-byte buffer or FIFO for transmission/reception
 - Timeout management
 - Identifier filters
 - DMA interface
 - Support for 16 identifiers
 - Master mode with autonomous message handling
 - Wakeup event on dominant bit detection
 - True LIN field state machine
 - Advanced LIN error detection
 - Header, response and frame timeout
 - Slave mode
 - * Autonomous header handling
 - * Autonomous transmit/receive data handling
 - Identifier filters for autonomous message handling in slave mode
 - Separate clock for baud rate calculation
- UART mode features include:
 - Full-duplex communication
 - Separate clock for baud rate calculation
 - 7/8 bits data, parity
 - 1/2/3 stop bits
 - 12-bit + parity reception
 - 4-byte buffer for reception; 4-byte buffer for transmission
 - 12-bit counter for timeout management
 - The maximum baud rate achievable is $\text{ipg_baud_clk}/4$ Mbit/s
 - For bit rate $\leq \text{ipg_baud_clk}/16$ Mbit/s
 - * 16 times oversampling
 - * 3:1 majority voting
 - For $\text{ipg_baud_clk}/16$ Mbit/s $<$ bit rate $\leq \text{ipg_baud_clk}/8$ Mbit/s
 - * Reduced oversampling programmable by software
 - * 3:1 majority voting for reduced oversampling of 8 samples per bit
 - For $\text{ipg_baud_clk}/8$ Mbit/s $<$ bit rate $\leq \text{ipg_baud_clk}/4$ Mbit/s
 - * Reduced oversampling programmable by software
 - * 1:1 voting for all reduced oversampling of 4, 5 and 6 samples per bit

4.7.3 Serial Peripheral Interface (SPI)

- Support clock polarity and phase configuration
- Configurable frame size
- Transmit/Receive FIFO
- Support single line mode
- Support Master and Slave mode

- Support Transmit/Receive via DMA

4.7.4 Inter-Integrated Circuit (I2C)

- Support standard, fast and ultra fast mode
- Support 7-bit/10-bit address mode with master and slave
- Support SMBus mode
- Support multi-master arbitration and synchronization
- Support Master and slave clock stretching
- Transmit/Receive FIFO (Master only)
- Analog and digital filter on both SCL and SDA pins
- Support Transmit/Receive via DMA

4.8 Human Machine Interface

4.8.1 General Purpose Input/Output (GPIO)

- Port Data Output register with corresponding set/clear/toggle registers
- Port Data Direction register
- Digital filter for data inputs
- Inversion for data inputs
- Interrupt flag and enable registers for each pin
- Support for edge sensitive (rising, falling, both) or level sensitive (low, high)
- Asynchronous wake-up in low-power modes
- Pin interrupt is functional in all digital pin muxing modes

4.8.2 Port Controller (PCTRL)

- Individual pull control fields with pullup, pulldown, and pull-disable support
- Individual slew rate field supporting fast and slow slew rates
- Individual input passive filter field supporting enable and disable of the individual input passive filter on selected pins
- Individual high drive strength enable on selected pins.
- Individual mux control field supporting analog or pin disabled, GPIO, and up to 6 chip-specific digital functions

5 Ordering Information

The following chips are available for ordering.

Table 1: Ordering Table

Product	Memory		Package		IO and ADC channel		Communication
Part number	Flash	SRAM	Pin count	Package	GPIOs (Normal)	ADC channels	FlexCAN
YTM32B1ME05G0MLQT	1.25MB	128KB	144	LQFP	126	48	6
YTM32B1ME05G0MLQCT	1.25MB	128KB	144	LQFP	126	48	6
YTM32B1ME05G0MLLT	1.25MB	128KB	100	LQFP	87	32	6
YTM32B1ME05G0MLLCT	1.25MB	128KB	100	LQFP	87	32	6
YTM32B1ME05G0MLHT	1.25MB	128KB	64	LQFP	56	27	6

Table 1 continued from previous page

Product	Memory		Package		IO and ADC channel		Communication
Part number	Flash	SRAM	Pin count	Package	GPIOs (Normal)	ADC channels	FlexCAN
YTM32B1ME05G0MLHCT	1.25MB	128KB	64	LQFP	56	27	6
YTM32B1ME05G0MLHIT	1.25MB	128KB	64	LQFP	56	27	6

5.1 Part Numbers

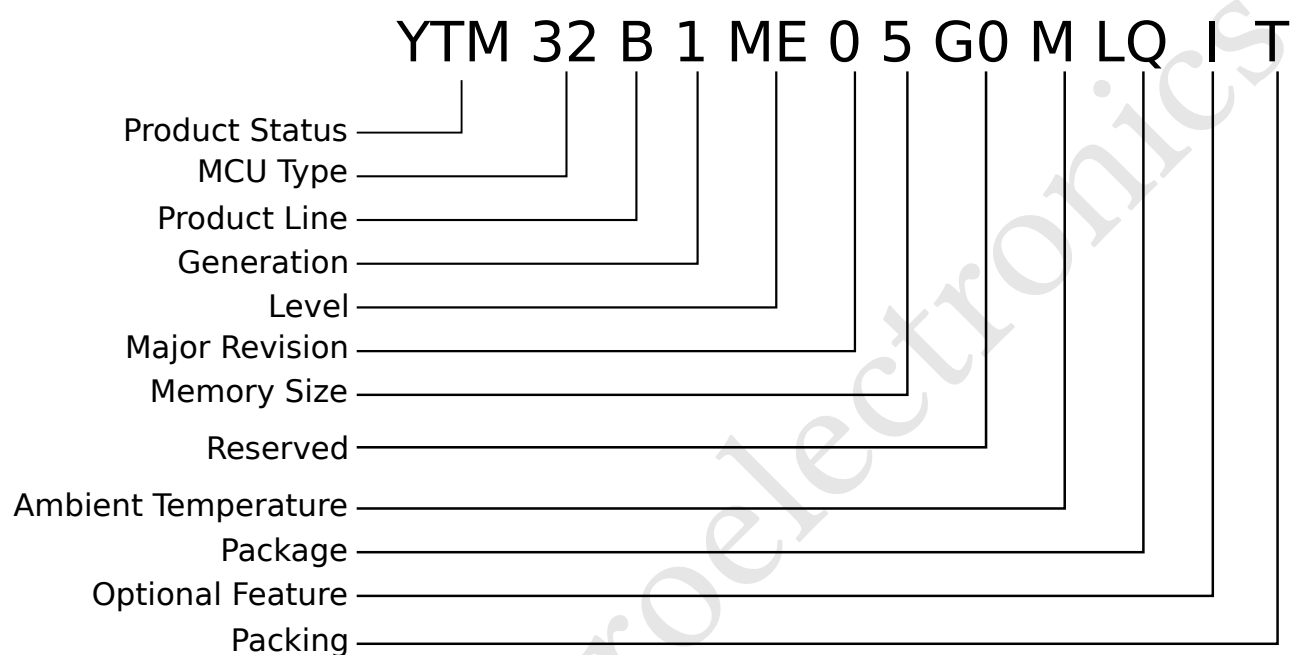


Figure 2: Part Numbers Field

The part numbers field description is shown as below.

Table 2: Part Number Field Description

Field	Description	Values
YTM	Product Status	YTM: Qualified PTM: Prototype
32	MCU Type	32: 32-bit
B	Product Line	B: General D: Dashboard P: Powertrain V: Vision N: Network
1	Generation	1st generation product
Mx	Level	Hx: High end Mx: Middle end Lx: Low end
0	Major Revision	1st revision

Table 2: Part Number Field Description

Field	Description	Values					
5	Memory Size		1	2	3	4	5
		H	2M	4M	6M	8M	-
		M	64K	128K	256K	512K	1M
		L	8K	16K	32K	64K	128K
G0	Reserved	Reserved					
M	Ambient Temperature	C: -40°C ~85°C V: -40°C ~105°C M: -40°C ~125°C W: -40°C ~150°C					
LQ	Package	Pin Counts	LQFP	QFN	BGA	-	-
		32	LE	FM	-	-	-
		48	LF	-	-	-	-
		64	LH	-	-	-	-
		100	LL	-	MH	-	-
		144	LQ	-	-	-	-
		176	LU	-	-	-	-
		257	-	-	MM	-	-
		289	-	-	MQ	-	-
I	Optional Feature	I: ISELED C: Cost Optimization					
T ¹	Packing	T: Trays/Tubes R: Tape and Reel					

1. The chip mark will not contain packing information

6 Electrical Characteristics

6.1 Ratings

6.1.1 Thermal Operating Characteristics

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
T _A M-Grade Part	Ambient temperature under bias	-40	-	125	°C
T _J M-Grade Part	Junction temperature under bias	-40	-	150	°C

6.1.2 Moisture Handling Ratings

Symbol	Description	Min.	Typ.	Max.	Notes
MSL	Moisture sensitivity level	-	3	-	1

NOTE:

- Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices
- Storage conditions are formulated in accordance with MSL3 standards. For specific requirements, refer to the instructions on the aluminum foil packaging bag. Chip storage shall meet the following: temperature < 40°C, humidity < 90% RH, storage period 24 months.

6.1.3 ESD Handling Ratings

Symbol	Description	Min.	Max.	Unit	Notes
V_{HBM}	Electrostatic discharge voltage, human body model	-4000	4000	V	1
V_{CDM}	Electrostatic discharge voltage, charged-device model				2
	All pins except the corner pins	-500	500	V	
	Corner pins only	-750	750	V	
I_{LAT}	Latch-up current at ambient temperature of 125 °C	-100	100	mA	3
	Latch-up current at ambient temperature of 25 °C	-200	200	mA	

1. Determined according to JEDEC Standard JESD22-A114, Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)
2. Determined according to JEDEC Standard JESD22-C101, Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components
3. Determined according to JEDEC Standard JESD78, IC Latch-Up Test.

6.2 DC Characteristics

6.2.1 Absolute Maximum Ratings

Symbol	Description	Min.	Max.	Unit	Notes
V_{DD}	Supply voltage	-0.3	5.8 ¹	V	
I_{VDD}	Maximum current into V_{DD}	–	150	mA	
V_{IO}	Digital/Analog IO Input voltage	-0.3	$V_{\text{DD}} + 0.3$	V	
I_{O}	Instantaneous maximum current of single pin	-25	25	mA	
V_{DDA}	Analog supply voltage	$V_{\text{DD}} - 0.3$	$V_{\text{DD}} + 0.3$	V	

1. 60 seconds lifetime - No restrictions i.e. the part is not held in reset and can switch.
- 10 hours lifetime - The part is held in reset by an external circuit i.e. the part cannot switch.

NOTE:

- The maximum ratings are the limits to which the device can be subjected without permanently damaging the device.
- The device is not guaranteed to operate properly at the maximum ratings. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

6.2.2 Voltage and Current Operating Requirements

Symbol	Description	Min.	Max.	Unit	Notes
V_{DD}	Supply voltage	2.97	5.5	V	
V_{DDA}	Analog supply voltage	2.97	V_{DD}	V	
V_{REFH}	Reference voltage	2.97	V_{DDA}	V	
$V_{DD} - V_{DDA}$	V_{DD} to V_{DDA} differential voltage	-0.1	0.1	V	
I_{ICIO}^1	Continuous DC input current (positive / negative) that can be injected into an I/O pin	-1	1	mA	
I_{Ccont}	Contiguous pin DC injection current – regional limit, includes sum of positive rejection currents of 16 contiguous pins	–	15	mA	
T_{ramp}	MCU supply ramp rate	5 V/100ms	100 V/ms	–	

1. All pins are internally clamped to V_{SS} and V_{DD} through ESD protection diodes. If V_{IN} is less than $V_{SS} - 0.3V$ or greater than $V_{DD} + 0.3V$, a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as $R = (V_{SS} - 0.3V - V_{IN}) / |I_{ICIO}|$. The positive injection current limiting resistor is calculated as $R = [V_{IN} - (V_{DD} + 0.3V)] / |I_{ICIO}|$. The actual resistor values should be an order of magnitude higher to tolerate transient voltages.

6.2.3 DC Electrical Specifications at 3.3V

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V_{DD}	I/O supply voltage	2.97	3.3	4.0	V	
V_{ih}	Input buffer high voltage	$0.7 * V_{DD}$	–	$V_{DD} + 0.3$	V	
V_{il}	Input buffer low voltage	$V_{SS} - 0.3$	–	$0.3 * V_{DD}$	V	
V_{hys}	Input buffer hysteresis	$0.05 * V_{DD}$	–	$0.3 * V_{DD}$	V	
I_{oh}	Normal drive I/O current source capability measured when pad = $(V_{DD} - 0.8V)$	4	10.4	–	mA	
I_{ol}	Normal drive I/O current sink capability measured when pad = 0.8V	3	11.4	–	mA	
I_{oh}	High drive I/O current source capability measured when pad = $(V_{DD} - 0.8V)$	7	–	–	mA	
I_{ol}	High drive I/O current sink capability measured when pad = 0.8V	7	–	–	mA	
I_{leak}	Hi-Z (Off state) leakage current (per pin) @25°C	–	–	8	nA	
	Hi-Z (Off state) leakage current (per pin) @125°C	–	–	8	μA	
V_{OH}	Output high voltage					
	Normal drive pad ($2.97V \leq V_{DD} \leq 4.0V$, $I_{OH} = -2.8mA$)	$V_{DD} - 0.8$	–	V_{DD}	V	

Table 8 continued from previous page

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V _{OL}	Output low voltage					
	Normal drive pad (2.97V ≤ V _{DD} ≤ 4.0V, I _{OL} = -2.8mA)	V _{SS}	–	0.8	V	
I _{OLT}	Output low current total for all ports	–	–	70	mA	
I _{IN}	Input leakage current (per pin) for full temperature range					
	Normal pins	–	0.002	0.6	μA	
	High Drive pins	–	0.005	0.6	μA	
R _{PU}	Internal pull-up resistors	20	–	100	kΩ	
R _{PD}	Internal pull-down resistors	20	–	105	kΩ	

6.2.4 DC Electrical Specifications at 5.0V

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V _{DD}	I/O supply voltage	4	5	5.5	V	
V _{ih}	Input buffer high voltage	0.7 * V _{DD}	–	V _{DD} + 0.3	V	
V _{il}	Input buffer low voltage	V _{SS} - 0.3	–	0.3 * V _{DD}	V	
V _{hys}	Input buffer hysteresis	0.05 * V _{DD}	–	0.3 * V _{DD}	V	
I _{oh}	Normal drive I/O current source capability measured when pad = (V _{DD} - 0.8V)	5	10	–	mA	
I _{ol}	Normal drive I/O current sink capability measured when pad = 0.8V	5	10	–	mA	
I _{oh}	High drive I/O current source capability measured when pad = (V _{DD} - 0.8V)	9	–	–	mA	
I _{ol}	High drive I/O current sink capability measured when pad = 0.8V	9	–	–	mA	
I _{leak}	Hi-Z (Off state) leakage current (per pin) @25°C	–	–	8	nA	
	Hi-Z (Off state) leakage current (per pin) @125°C	–	–	8	μA	
V _{OH}	Output high voltage					
	Normal drive pad (4V ≤ V _{DD} ≤ 5.5V, I _{OH} = -2.8mA)	V _{DD} - 0.8	–	V _{DD}	V	
V _{OL}	Output low voltage					
	Normal drive pad (4V ≤ V _{DD} ≤ 5.5V, I _{OL} = -2.8mA)	V _{SS}	–	0.8	V	
I _{OLT}	Output low current total for all ports	–	–	70	mA	

Table 9 continued from previous page

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
I _{IN}	Input leakage current (per pin) for full temperature range					
	Normal pins	–	0.002	0.6	μA	
	High Drive pins	–	0.005	0.6	μA	
R _{PU}	Internal pull-up resistors	20	–	70	kΩ	
R _{PD}	Internal pull-down resistors	20	–	70	kΩ	

6.2.5 Power and Ground Pins

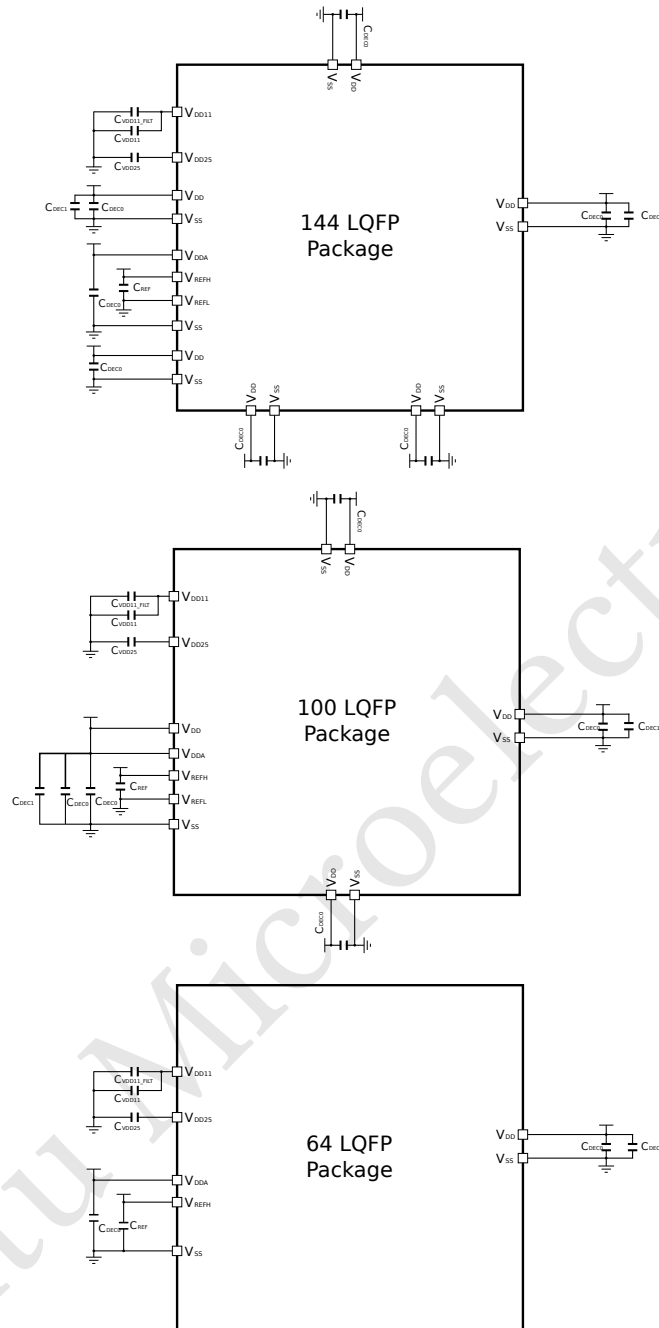


Figure 3: Pinout Decoupling

Symbol	Description	Min.	Typ.	Max.	Unit
$C_{REF}^{1,2}$	ADC reference high decoupling capacitance	50	100	200	nF
$C_{DEC0}^{2,3}$	Recommended decoupling capacitance for V_{DD5}	1	2.2	10	μ F
$C_{DEC1}^{2,3}$	Recommended bypass decoupling capacitance for V_{DD5}	50	100	200	nF

Table 10 continued from previous page

Symbol	Description	Min.	Typ.	Max.	Unit
C _{VDD11}	Internal PMC, LDO voltage	1	2.2	10	μF
C _{VDD11_FILT}	Internal PMC, LDO voltage, ripple filter	50	100	200	nF
C _{VDD25}	Internal PMC, LDO voltage	0.1	0.22	1	μF

1. For improved ADC performance it is recommended to use 1 nF X7R/C0G and 10 nF X7R ceramics in parallel.
2. The capacitors should be placed as close as possible to the VREFH/VREFL pins or corresponding VDD/VSS pins.
3. The requirement and value of CDEC will be decided by the device application requirement.

6.2.6 POR, LVR and LVD Operating Requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V _{POR}	Rising and falling V _{DD} POR detect voltage	1.3	1.7	2.1	V	
V _{LVD}	Falling low-voltage threshold	2.7	–	2.9	V	
V _{LVD_HYST}	LVD hysteresis	–	20	–	mV	

6.2.7 Power Mode Transition Operating Behaviors

Description	System clock	Frequency	Min.	Typ.	Max.
SLEEP -> ACTIVE	FIRC	96MHz	–	800ns	–
SLEEP -> ACTIVE	FXOSC	24MHz	–	14.2μs	–
SLEEP -> ACTIVE	PLL	120MHz	–	200ns	–
DEEPSLEEP -> ACTIVE	FIRC	96MHz	–	800ns	–
DEEPSLEEP -> ACTIVE	FXOSC	24MHz	–	584μs	–
DEEPSLEEP -> ACTIVE	PLL	120MHz	–	907μs	–
STANDBY -> ACTIVE	FIRC	96MHz	–	800ns	–
STANDBY -> ACTIVE	FXOSC	24MHz	–	900μs	–
STANDBY -> ACTIVE	PLL	120MHz	–	951μs	–
POWERDOWN -> ACTIVE	FIRC	96MHz	–	120μs	–
POWERDOWN -> ACTIVE	FXOSC	24MHz	–	228μs	–
POWERDOWN -> ACTIVE	PLL	120MHz	–	202μs	–
T _{POR}	FIRC(reset value)	96MHz	–	350μs	–

6.2.8 Power Consumption

Mode	Symbol	Clock configuration	Description	Temperature	Min	Typ	Max	Units
ACTIVE	I _{DD_ACTIVE}	PLL	Running while(1) loop in sram, all peripheral clock disabled. core @120MHz V _{DD} =5V	≤ 25 °C	–	17.4	30	mA
				125 °C	–	20	40	mA
SLEEP	I _{DD_SLEEP}	PLL	Sleep mode current, V _{DD} =5V Core Frequency @120MHz SIRC, SXOSC enabled	≤ 25 °C	–	11.7	20	mA
				125 °C	–	14.0	30	mA
DEEPSLEEP	I _{DD_DEEPSLEEP}	PLL	Deepsleep mode current, V _{DD} =5V SIRC, SXOSC disabled	≤ 25 °C	–	1.9	10	mA
				125 °C	–	3.9	15	mA
STANDBY	I _{DD_STANDBY}	PLL	Standby mode current, V _{DD} =5V SIRC, SXOSC disabled	≤ 25 °C	–	251.1	600	μA
				125 °C	–	2.1	8	mA
POWERDOWN	I _{DD_POWERDOWN}	PLL	Powerdown mode current, V _{DD} =5V SIRC, SXOSC disabled	≤ 25 °C	–	45.2	150	μA
				125 °C	–	264.7	700	μA

6.2.9 Power Sequence

6.2.9.1 Power Up Sequence

Hardwares must follow the sequence below to ensure that the chip is powered up properly.

1. VDD must be powered up first.
2. VDDA must be powered up later than or at the same time as VDD.
3. VREFH must be powered up later than or at the same time as VDDA.

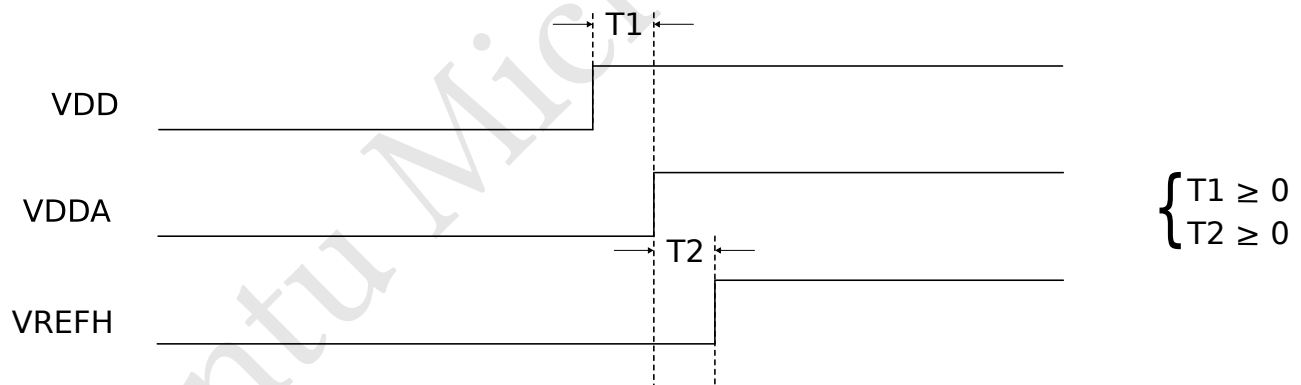


Figure 4: Power Sequence

6.2.9.2 MCU Power Supply Ramp Rate

During the power-up sequence of MCU, it is critical that the power supply maintains a ramp-rate within the specified range, starting from V_{DD_OFF} at 0.1V and rising to the MCU's operational voltage level (V_{DD}). Failure to comply with this specification may result in unintended behavior, operational stagnation or even damage to the MCU.

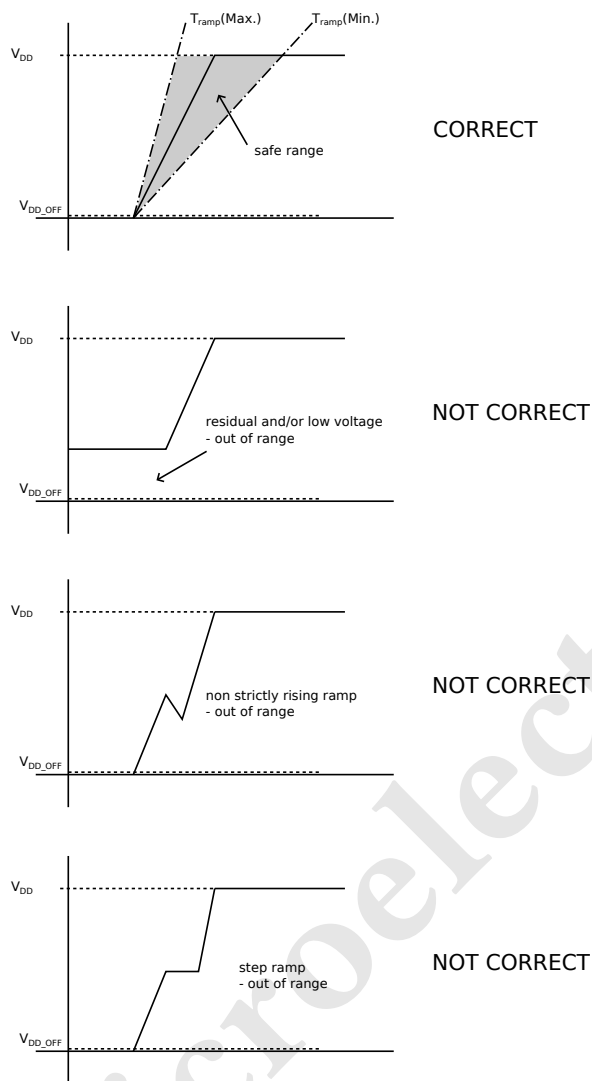


Figure 5: Power Supply Ramp Rate

6.3 AC Characteristics

6.3.1 Power Supply Fluctuation Requirements

1. The power supply fluctuation must be maintained within $\pm 10\%$ of the power supply voltage, and the fluctuation frequency should not exceed 100 KHz.
2. The maximum power supply fluctuation should not exceed $\pm 20\%$ of the power supply voltage, and in this case, the fluctuation frequency should be less than 30 KHz.
3. Power supply fluctuations exceeding the above requirements may cause chip abnormalities.

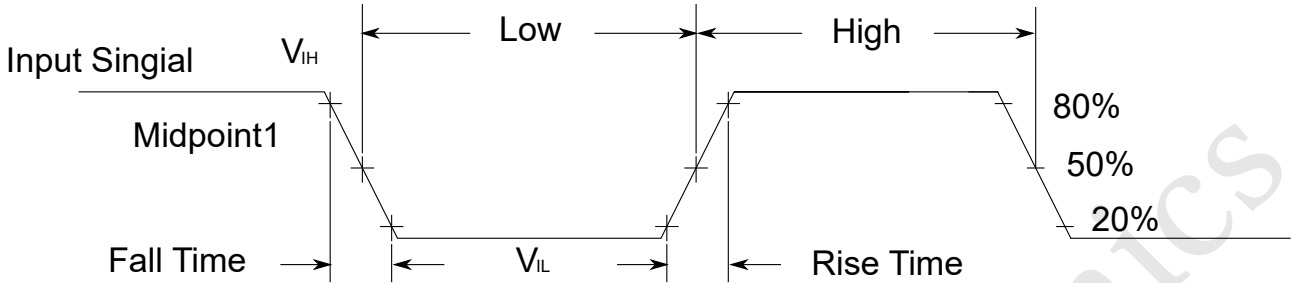
6.3.2 Device Clock Specifications

Symbol	Description	Min.	Max.	Unit	Notes
f_{core}	System and core clock	—	120	MHz	
f_{bus}	Fast bus clock	—	120	MHz	
f_{sbus}	Slow bus clock	—	40	MHz	

6.3.3 I/O Electrical Characteristics

6.3.3.1 AC Electrical Characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and the rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is $V_{IL} + (V_{IH} - V_{IL}) / 2$

Figure 6: Input Signal Measurement Reference

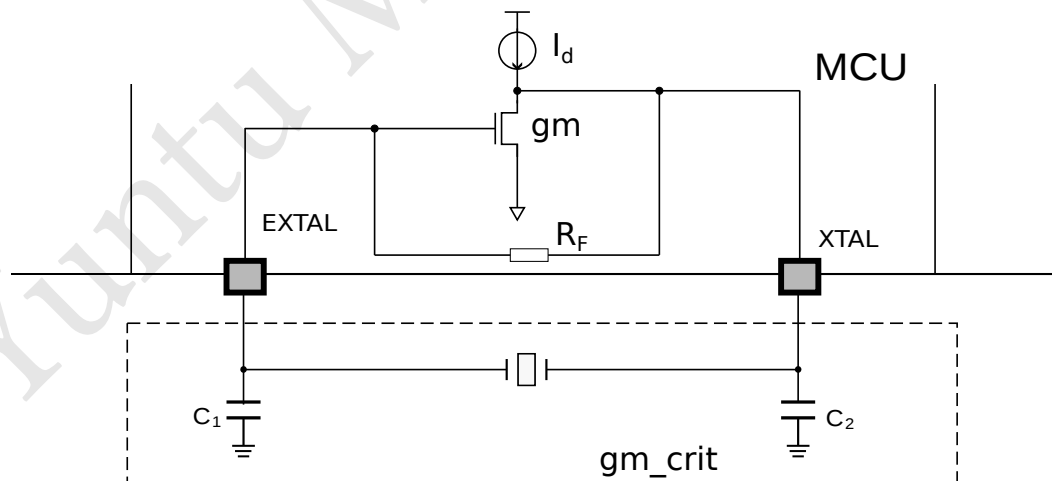
All digital I/O switching characteristics, unless otherwise specified, assume that the output pins have the following characteristics.

- $C_L = 30\text{pF}$ loads
- Normal drive strength

6.4 Peripheral Operating Requirements and Behaviors

6.4.1 FXOSC(4~40 MHz) Characteristics

The following diagram is FXOSC circuit.



■ The internal circuitry of the chip utilizes an I_d current source as the load for the amplifier circuit, with an NMOS transistor serving as the amplifying transistor. When the gain (g_m) of the amplifying transistor is greater than the intrinsic gain (g_{m_crit}) of the external crystal oscillator, theoretically, the crystal oscillator will start to oscillate. Generally, it is required that $g_m > 5 * g_{m_crit}$.

■ R_F provides the DC bias point for the input terminal of the amplifying transistor.

Figure 7: FXOSC Diagram

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
I _{DDOSC}	FXOSC oscillator	–	0.8	–	mA	
V _{IH}	Input high voltage – EXTAL pin in external clock mode, V _{DD} =5V	V _{DD} * 0.7	–	V _{DD}	V	
	Input high voltage – EXTAL pin in external clock mode, V _{DD} =3.3V	V _{DD} * 0.7	–	V _{DD}	V	
V _{IL}	Input low voltage – EXTAL pin in external clock mode, V _{DD} =5V	V _{SS}	–	V _{DD} * 0.3	V	
	Input low voltage – EXTAL pin in external clock mode, V _{DD} =3.3V	V _{SS}	–	V _{DD} * 0.3	V	
T _{FXOSCSU}	FXOSC startup time (24MHz oscillator)	–	0.5	–	ms	
D _{FXOSC}	Duty of FXOSC (24MHz oscillator)	45	50	55	%	
F _{FXOSC}	FXOSC frequency range	4	–	40	MHz	
C ₁	Load capacitance	–	–	–	pF	1
C ₂	Load capacitance	–	–	–	pF	
R _F	FXOSC internal feedback resistor	350	500	650	KΩ	
V _{PP}	Peak-to-peak amplitude of oscillation (24MHz oscillator)	0.7	–	V _{DD25}	V	

1. Crystal oscillator circuit provides stable oscillations when $gm > 5 * gm_{crit}$. The gm_{crit} is defined as:
 $gm_{crit} = 4 * (ESR + R_S) * (2\pi F)^2 * (C_0 + C_L)^2$

where:

- gm is the transconductance of the internal oscillator circuit
- ESR is the equivalent series resistance of the external crystal
- R_S is the series resistance connected between XTAL pin and external crystal for current limitation
- F is the external crystal oscillation frequency
- C_0 is the shunt capacitance of the external crystal
- C_L is the external crystal total load capacitance. $C_L = C_S + [C_1 * C_2 / (C_1 + C_2)]$
- C_S is stray or parasitic capacitance on the pin due to any PCB traces
- C_1 and C_2 are external load capacitances on EXTAL and XTAL pins

Table 16: Startup Time - Gain Selection for gm of 40MHz Crystal Oscillator Circuits (Simulation)

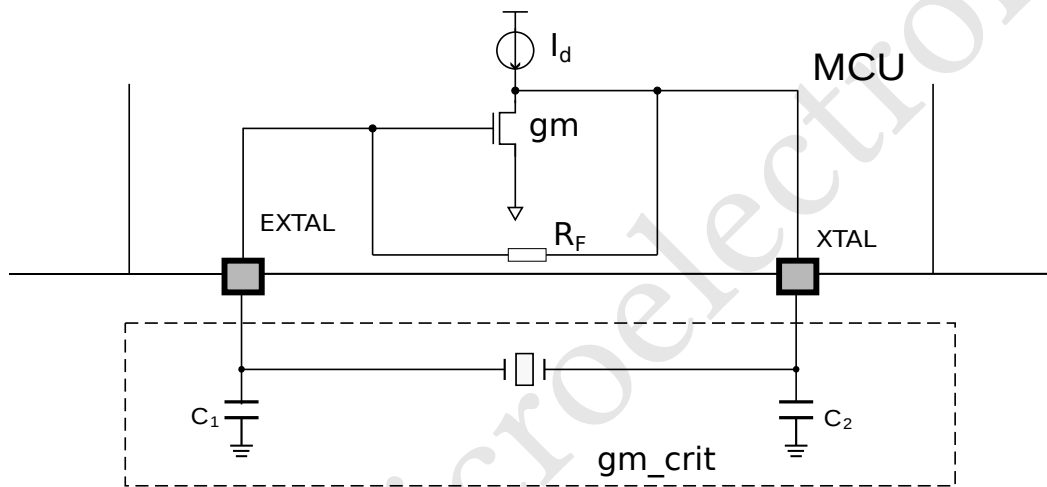
Gain Setting	gm (at startup)			Unit
	Min.	Typ.	Max.	
0			0	mS
1	1.1	1.3	1.5	mS
2	2.2	2.6	3.0	mS
3	3.3	3.8	4.5	mS
4	2.5	3.0	3.5	mS
5	3.6	4.3	5.0	mS
6	4.7	5.5	6.5	mS
7	5.8	6.8	8.0	mS
8	5.1	6.0	7.0	mS
9	6.2	7.2	8.5	mS

Table 16 continued from previous page

Gain Setting	gm (at startup)			Unit
	Min.	Typ.	Max.	
10	7.3	8.5	10.0	mS
11	8.3	9.8	11.5	mS
12	7.6	8.9	10.5	mS
13	8.7	10.2	12.0	mS
14	9.8	11.5	13.5	mS
15	10.9	12.8	15.1	mS

6.4.2 SXOSC(32.768 KHz) Characteristics

The following diagram is SXOSC circuit.



■ The internal circuitry of the chip utilizes an I_d current source as the load for the amplifier circuit, with an NMOS transistor serving as the amplifying transistor. When the gain (g_m) of the amplifying transistor is greater than the intrinsic gain (g_{m_crit}) of the external crystal oscillator, theoretically, the crystal oscillator will start to oscillate. Generally, it is required that $g_m > 5 * g_{m_crit}$.

■ R_F provides the DC bias point for the input terminal of the amplifying transistor.

Figure 8: SXOSC Diagram

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
F_{SXOSC}	Oscillator crystal frequency	–	32.768	–	KHz	
I_{DDOSC}	SXOSC oscillator	–	6.5	–	μA	
$T_{startup}$	SXOSC startup time (32.768KHz oscillator)	–	–	1	s	
D_{SXOSC}	Duty of SXOSC (32.768KHz oscillator)	30	50	65	%	
C_1	Load capacitance	–	–	–	pF	1
C_2	Load capacitance	–	–	–	pF	
R_F	SXOSC internal feedback resistor	4.8	6	7.2	M Ω	
V_{PP}	Peak-to-peak amplitude of oscillation (32.768KHz oscillator)	1.6	2.4	V_{DD}	V	

1. Crystal oscillator circuit provides stable oscillations when $g_m > 5 * g_{m_crit}$. The g_{m_crit} is defined as:

$$gm_crit = 4 * (ESR + R_S) * (2\pi F)^2 * (C_0 + C_L)^2$$

where:

- gm is the transconductance of the internal oscillator circuit. $gm > 10 \mu S$
- ESR is the equivalent series resistance of the external crystal
- R_S is the series resistance connected between XTAL pin and external crystal for current limitation
- F is the external crystal oscillation frequency
- C_0 is the shunt capacitance of the external crystal
- C_L is the external crystal total load capacitance. $C_L = C_S + [C_1 * C_2 / (C_1 + C_2)]$
- C_S is stray or parasitic capacitance on the pin due to any PCB traces
- C_1 and C_2 are external load capacitances on EXTAL and XTAL pins

6.4.3 PLL Characteristics

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
F_{ref}	PLL reference frequency range	8	–	96	MHz	
F_{input}	PLL input frequency	8	–	24	MHz	5
F_{vco}	VCO frequency	200	–	240	MHz	
F_{out}	Out frequency	100	–	120	MHz	1, 4
N_{pre}	Reference clock predivider	1	–	16		2
N_{div}	VCO feedback divider	10	–	64		3
T_{lock}	PLL lock time	–	$5120 * T_{input}$	–		6

1. PLL OUT divider is 2, $F_{out} = F_{vco} / 2$

2. PLL clock pre-divider is from 1 to 16. If need to re-configure. It is recommended to switch to other clock source, then disable PLL, and configure PLL predivider, switch to PLL, and enable it finally.

3. PLL clock feedback divider is from 10 to 63. It is recommended to switch to other clock source, then disable PLL, and configure PLL predivider, switch to PLL, and enable it finally.

4. $F_{out} = \frac{F_{ref}}{2 * N_{pre}} * N_{div}$

5. $F_{input} = \frac{F_{ref}}{N_{pre}}$

6. T_{input} represents the PLL input period

6.4.4 FIRC(96 MHz) Characteristics

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
F_{FIRC}	Fast internal reference frequency	–	96	–	MHz	
ACC_{FIRC}	FIRC frequency accuracy, factory trimmed, 25 °C	-2.0	–	2.0	%	
	FIRC frequency accuracy, factory trimmed, 125 °C	-3.5	–	3.5	%	
I_{FIRC}	FIRC operating current	–	90	–	μA	
$T_{Startup}$	Startup time	–	–	3	μs	

NOTE:

- For CAN communication, high-precision clock sources (e.g., FXOSC, PLL) must be used to comply with ISO 11898-1 standard; FIRC is not recommended for direct use as the PE clock of FlexCAN.
- For LIN/UART communication, it is recommended to use high-precision clock sources (e.g., FXOSC, PLL); if FIRC is used, evaluation must be conducted on frequency differences between chips, temperature effects, and frequency deviations of other devices in LIN/UART network.
- For applications with high requirements on the absolute frequency of the clock (e.g., PWM output, timing tasks), evaluation must be conducted on frequency differences between FIRC and SIRC among different chips and their temperature effects.

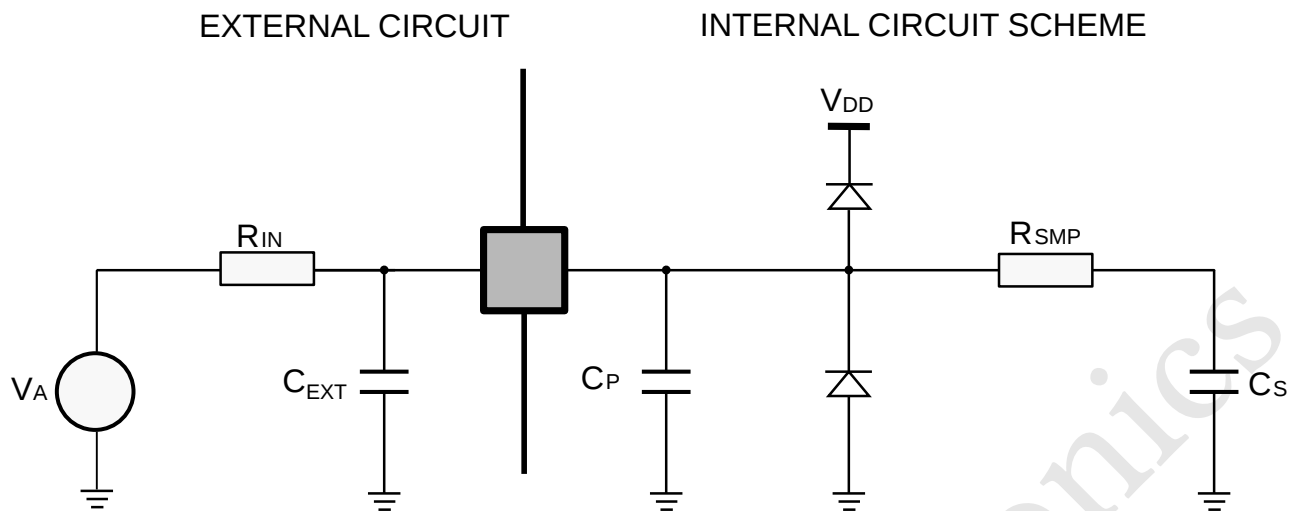
6.4.5 SIRC(12 MHz) Characteristics

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
F_{SIRC}	Slow internal reference frequency	–	12	–	MHz	
ACC_{SIRC}	SIRC frequency accuracy, factory trimmed, 25 °C	-10	–	10	%	
	SIRC frequency accuracy, factory trimmed, 125 °C	-20	–	20	%	
I_{SIRC}	SIRC operating current	–	9.2	–	μA	
$T_{Startup}$	Startup time	–	–	10	μs	

NOTE:

- For CAN communication, high-precision clock sources (e.g., FXOSC, PLL) must be used to comply with ISO 11898-1 standard; FIRC is not recommended for direct use as the PE clock of FlexCAN.
- For LIN/UART communication, it is recommended to use high-precision clock sources (e.g., FXOSC, PLL); if FIRC is used, evaluation must be conducted on frequency differences between chips, temperature effects, and frequency deviations of other devices in LIN/UART network.
- For applications with high requirements on the absolute frequency of the clock (e.g., PWM output, timing tasks), evaluation must be conducted on frequency differences between FIRC and SIRC among different chips and their temperature effects.

6.4.6 ADC Characteristics



Note: R_{IN} is the internal resistance of signal source.

Figure 9: ADC Circuit

Symbol	Description	Test condition	Min.	Typ.	Max.	Unit	Notes
V_{DDA}	Analog supply voltage		2.97	5.0	5.5	V	
I_{DDA}	Analog supply current	V_{DD}, V_{DDA}, V_{REF} under 5V	–	1.35	–	mA	
ΔV_{DDA}	$V_{DD} - V_{DDA}$		0	–	100	mV	
V_{REFH}	Reference voltage		2.97	–	V_{DDA}	V	
I_{REFH}	Reference current		–	–	800	μA	
V_{IN}	Input voltage		0	–	V_{REFH}	V	
R_{SMP}	Sampling switch impedance		0.18	0.64	1.5	k Ω	
C_{EXT}	External capacitance		50	–	–	nF	
C_P	Pin capacitance		–	6	–	pF	
C_S	Sampling capacitance		–	6	7	pF	

Symbol	Description	Test condition ¹	Min.	Typ.	Max.	Unit	Notes
$T_{STARTUP}$	Analog startup time		2	–	–	μs	
T_{SAMPLE}	Sampling time		100	–	1000	ns	
T_{sample_TS}	Tempensor sampling time		500	–	2000	ns	

1. These parameters of this table can be configured by register, please refer to Reference Manual for details.

Symbol	Description	Test condition	Min.	Typ.	Max.	Unit	Notes
DNL	Differential nonlinear	12-bit resolution	–	±2	–	LSB	
INL	Integer nonlinear	12-bit resolution	–	±3	–	LSB	
E _{GAIN}	Gain error	12-bit resolution	–	0.7	–	LSB	
E _{OFFSET}	Offset error	12-bit resolution	–	1.6	–	LSB	
SINAD	Signal-to-noise-and-distortion ratio	12-bit resolution	–	62.4	–	dB	
ACC _{TS}	Temperature sensor accuracy		-10		10	°C	
K ¹	Slope of temperature and voltage curve	ADC sampling time=500ns		536.9		°C / V	
F _{ADC}	ADC conversion clock		4		32	MHz	2

1. $T = C - K \cdot V$, see Reference Manual for details.

2. ADC conversion clock = ADC function clock / [(ipc_divider + 1) * (adc_clock_div + 1)]

6.4.7 ACMP Characteristics

Symbol	Description	Test condition	Min.	Typ.	Max.	Unit	Notes
V _{ACMP} ¹	Analog supply voltage		2.97	5.0	5.5	V	
I _{ACMP_Low_Power}	Analog supply current in low power mode		–	4	–	μA	
I _{ACMP_High_Speed}	Analog supply current in high speed mode		–	105	–	μA	
V _{INOFFSET}	Analog input offset voltage		-10	–	10	mV	
V _{IN}	Analog input voltage		V _{SS}	–	V _{DD}	V	
V _{HYST0}	Analog comparator hysteresis 0		10	15	21	mV	
V _{HYST1}	Analog comparator hysteresis 1		16	26	37	mV	
V _{HYST2}	Analog comparator hysteresis 2		26	41	57	mV	
DAC _{DNL}	Differential nonlinear		–	±1	–	LSB	

1. ACMP connects to VDD.

6.4.8 SPI Characteristics¹

Num.	Symbol	Description	Conditions	Min.	Max.	Unit
	f _{func} ²	Functional frequency	Slave	–	40	MHz
			Master	–	40	MHz
			Master Loopback ⁴	–	40	MHz
1	f _{op}	Frequency of operation	Slave	–	12.5	MHz
			Master	–	20	MHz
			Master Loopback ⁴	–	20	MHz

Table 25 continued from previous page

Num.	Symbol	Description	Conditions	Min.	Max.	Unit
2	t_{SCK}	SCK period	Slave	80	–	ns
			Master	50	–	ns
			Master Loopback ⁴	50	–	ns
3	t_{PCSSCK} ⁵	PCS to SCK delay	Slave	–	–	ns
			Master	$(PCSSCK+1) * t_{delay}^3 - 22$	–	ns
			Master Loopback ⁴	$(PCSSCK+1) * t_{delay}^3 - 22$	–	ns
4	t_{SCKPCS} ⁶	After SCK delay	Slave	–	–	ns
			Master	$(SCKPCS+1) * t_{delay}^3 - 22$	–	ns
			Master Loopback ⁴	$(SCKPCS+1) * t_{delay}^3 - 22$	–	ns
5	t_{WSCK} ⁷	Clock (SCK) high or low time	Slave	$t_{SCK}/2 - 1$	$t_{SCK}/2 + 1$	ns
			Master	$t_{SCK}/2 - 1$	$t_{SCK}/2 + 1$	ns
			Master Loopback ⁴	$t_{SCK}/2 - 1$	$t_{SCK}/2 + 1$	ns
6	t_{setup}	Data setup time (inputs)	Slave	6	–	ns
			Master	23	–	ns
			Master Loopback ⁴	4	–	ns
7	t_{holdin}	Data hold time (inputs)	Slave	0	–	ns
			Master	0	–	ns
			Master Loopback ⁴	2	–	ns
8	t_{valid}	Data valid (after SCK edge)	Slave	–	26	ns
			Master	–	7	ns
			Master Loopback ⁴	–	7	ns
9	$t_{holdout}$	Data hold time (outputs)	Slave	0	–	ns
			Master	0	–	ns
			Master Loopback ⁴	0	–	ns
10	$t_{RI/FI}$	Rise/Fall time input	Slave	–	5	ns
			Master	–	5	ns
			Master Loopback ⁴	–	5	ns
11	$t_{RO/FO}$	Rise/Fall time output	Slave	–	7	ns
			Master	–	7	ns
			Master Loopback ⁴	–	7	ns

1. The trace length for the SCK pad should be kept as short as possible when used in Master loopback mode, and it does not support off-board communication.

2. f_{func} = SPI functional clock, which is generated from IPC.

3. $t_{delay} = (1/f_{op}) * 2^{TXCFG[PRESCALE]}$.

4. Master Loopback mode - In this mode SCK clock is delayed for sampling the input data which is enabled by setting SPI_CTRL[SPDEN] bit as 1.

5. Set the PCSSCK configuration bit as 0, for a minimum of 1 delay cycle of SPI delay clock, where PCSSCK ranges from 0 to 255.

6. Set the SCKPCS configuration bit as 0, for a minimum of 1 delay cycle of SPI delay clock, where SCKPCS ranges from 0 to 255.

7. While selecting odd dividers, ensure Duty Cycle is meeting this parameter.

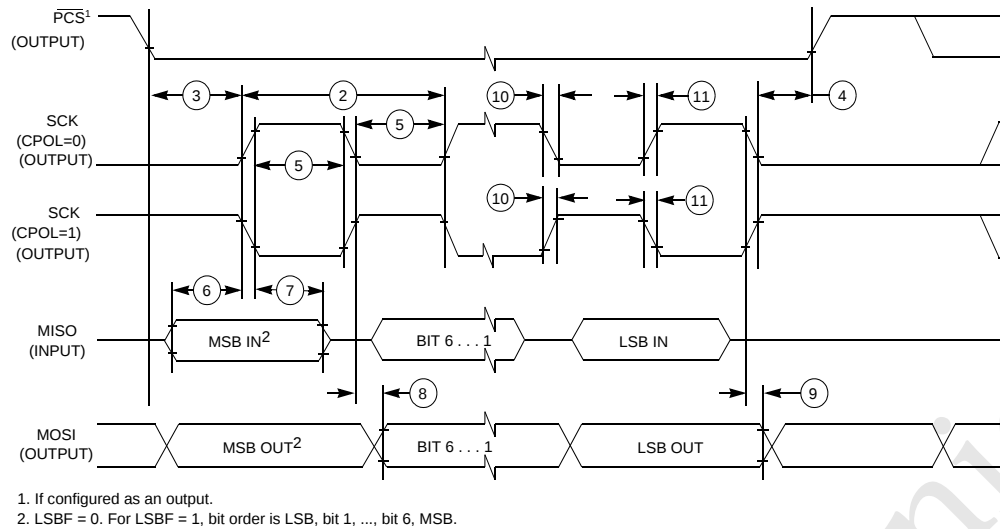


Figure 10: SPI Master Mode Timing (CHPA=0)

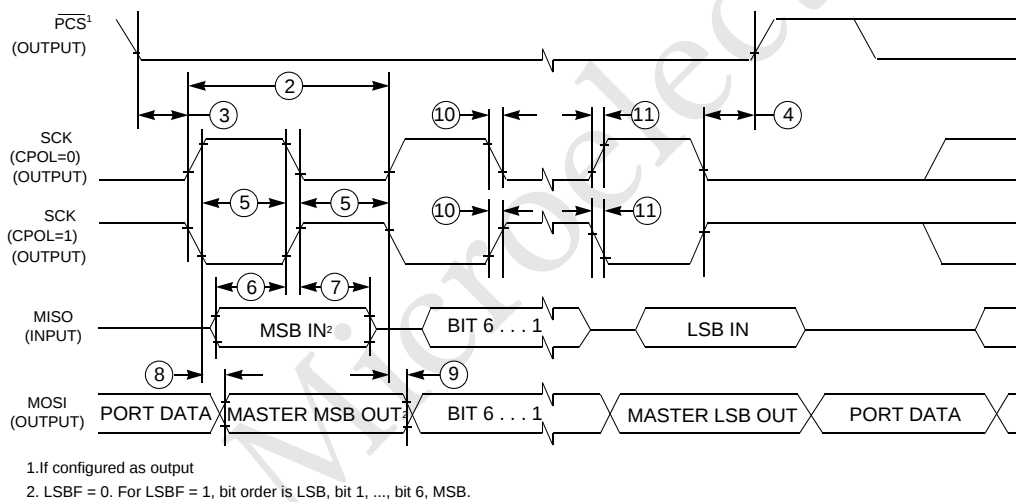
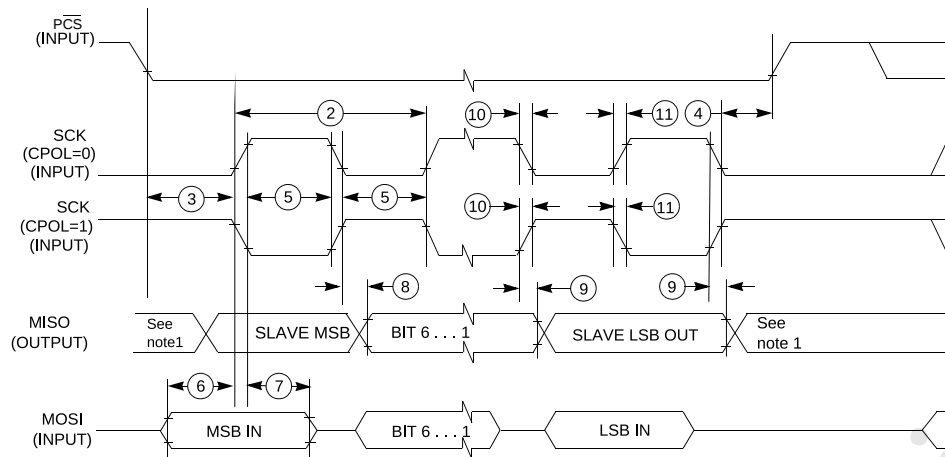
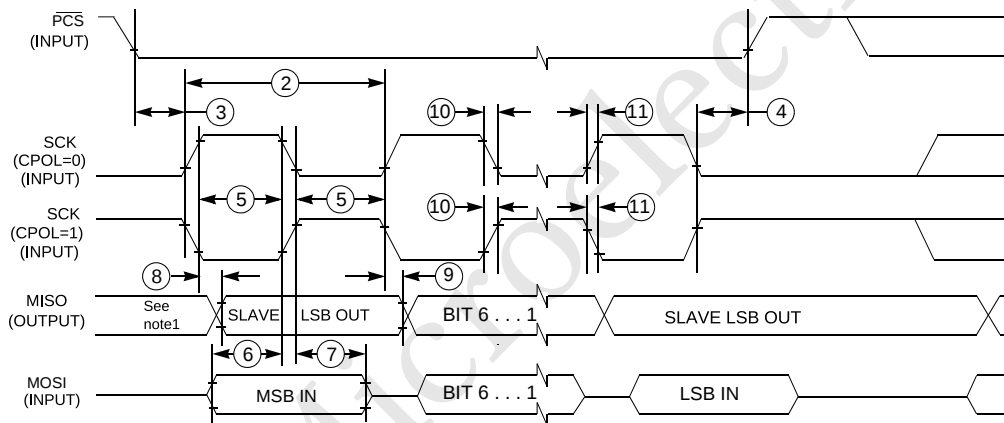


Figure 11: SPI Master Mode Timing (CHPA=1)



Notes:
1. The bus is driven but may not be equal to the valid serial data being sent.

Figure 12: SPI Slave Mode Timing (CHPA=0)



Notes:
1. The bus is driven but may not be equal to the valid serial data being sent.

Figure 13: SPI Slave Mode Timing (CHPA=1)

6.4.9 NVM Specifications

6.4.9.1 Flash Timing Specifications - Commands

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
T_{pgm}	Program execution time	–	45	47	μs	
T_{sector_erase}	Sector erase execution time	–	16	–	ms	
T_{block_erase}	Block erase execution time	–	16	–	ms	
T_{chip_erase}	Chip erase execution time	–	16	–	ms	
T_{erase_retry}	Erase retry execution time	–	1	16	ms	

6.4.9.2 Reliability Specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{\text{nvrmretp10k}}$	Data retention after up to 10K cycles	5	50	–	years	
$t_{\text{nvrmretp1k}}$	Data retention after up to 1K cycles	20	100	–	years	
t_{nvmeccp}	Cycling endurance	100,000	–	–	cycles	

6.4.10 Debug Module Electrical

6.4.10.1 SWD Electrical Specifications

Table 28: SWD Full Voltage Range Electricals

Symbol	Description	Min.	Typ.	Max.	Unit
T1	SWD_CLK frequency	–	–	20	MHz
T2	SWD_CLK cycle period	50	–	–	ns
T3	SWD_CLK pulse width	20	–	–	ns
T4	SWD_CLK rise and fall time	–	–	3	ns
T5	SWD_CLK input data setup time to SWD_CLK rise edge	8	–	–	ns
T6	SWD_CLK input data hold time after SWD_CLK rise edge	1.5	–	–	ns
T7	SWD_CLK high to SWD_DIO output data valid	–	–	35	ns
T8	SWD_CLK high to SWD_DIO output data Hi-Z	5	–	–	ns

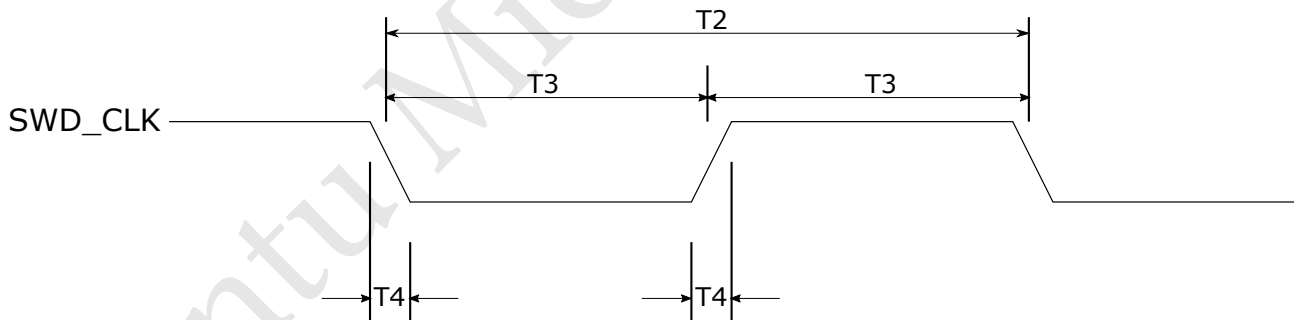


Figure 14: SWD Clock Timing

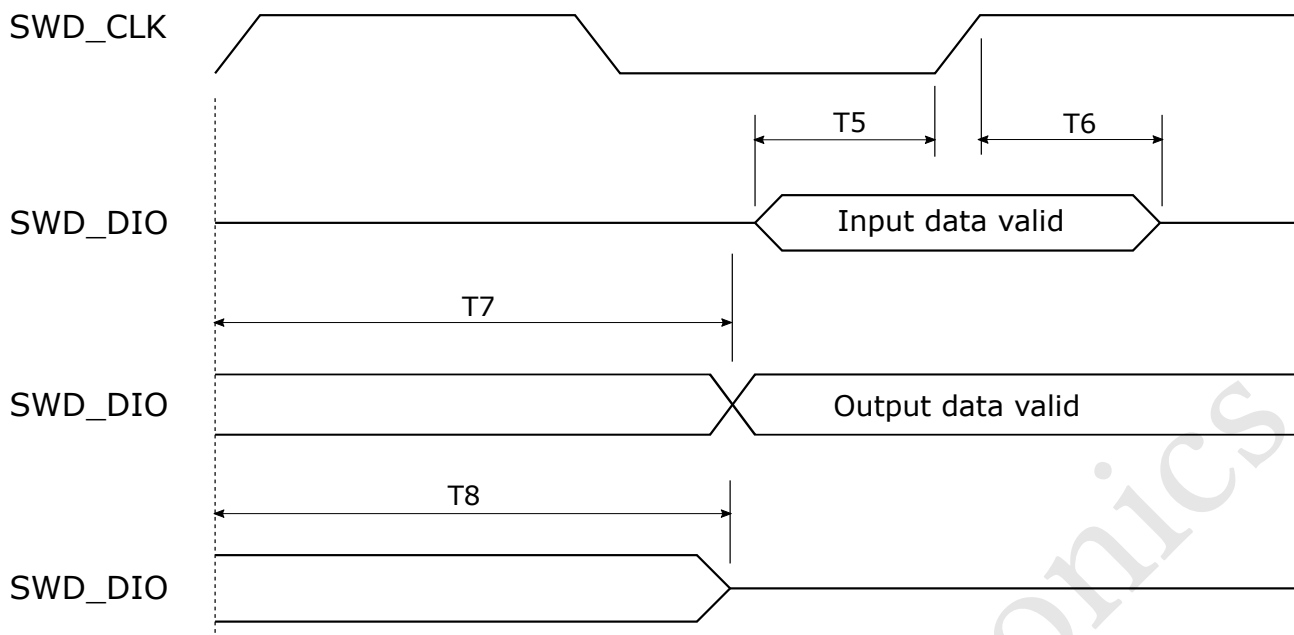


Figure 15: SWD Data Timing

6.4.10.2 JTAG Electrical Specifications

Table 29: JTAG Electrical Specifications

Symbol	Description	Active				Unit
		5.0V IO		3.3V IO		
		Min.	Max.	Min.	Max.	
J1	TCLK frequency					MHz
	Boundary Scan	–	20	–	20	
	JTAG	–	20	–	20	
J2	TCLK cycle period	1/J1	–	1/J1	–	ns
J3	TCLK clock pulse width					ns
	Boundary Scan	J2/2 - 5	J2/2 + 5	J2/2 - 5	J2/2 + 5	
	JTAG					
J4	TCLK rise and fall times	–	1	–	1	ns
J5	Boundary scan input data setup time to TCLK rise	5	–	5	–	ns
J6	Boundary scan input data hold time after TCLK rise	5	–	5	–	ns
J7	TCLK low to boundary scan output data valid	–	28	–	32	ns
J8	TCLK low to boundary scan output data invalid	0	–	0	–	ns
J9	TCLK low to boundary scan output high-Z	–	28	–	32	ns
J10	TMS, TDI input data setup time to TCLK rise	3	–	3	–	ns
J11	TMS, TDI input data hold time after TCLK rise	2	–	2	–	ns
J12	TCLK low to TDO data valid	–	28	–	32	ns
J13	TCLK low to TDO data invalid	0	–	0	–	ns
J14	TCLK low to TDO high-Z	–	28	–	28	ns

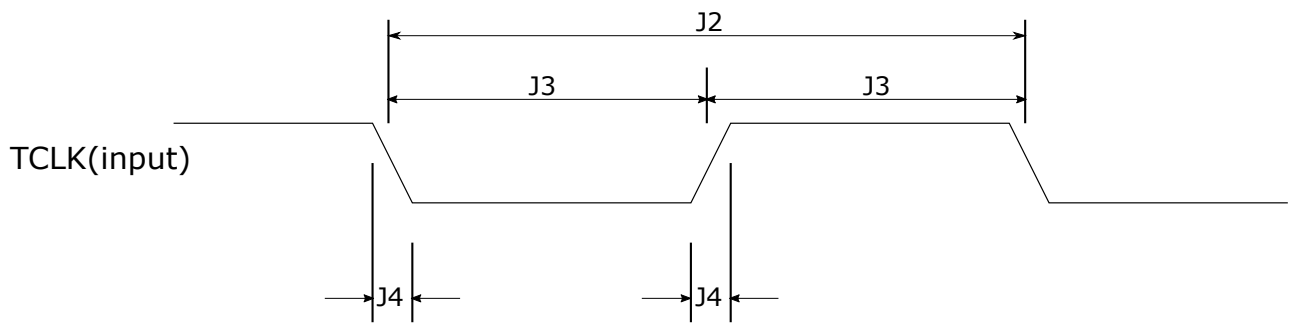


Figure 16: JTAG Clock Timing

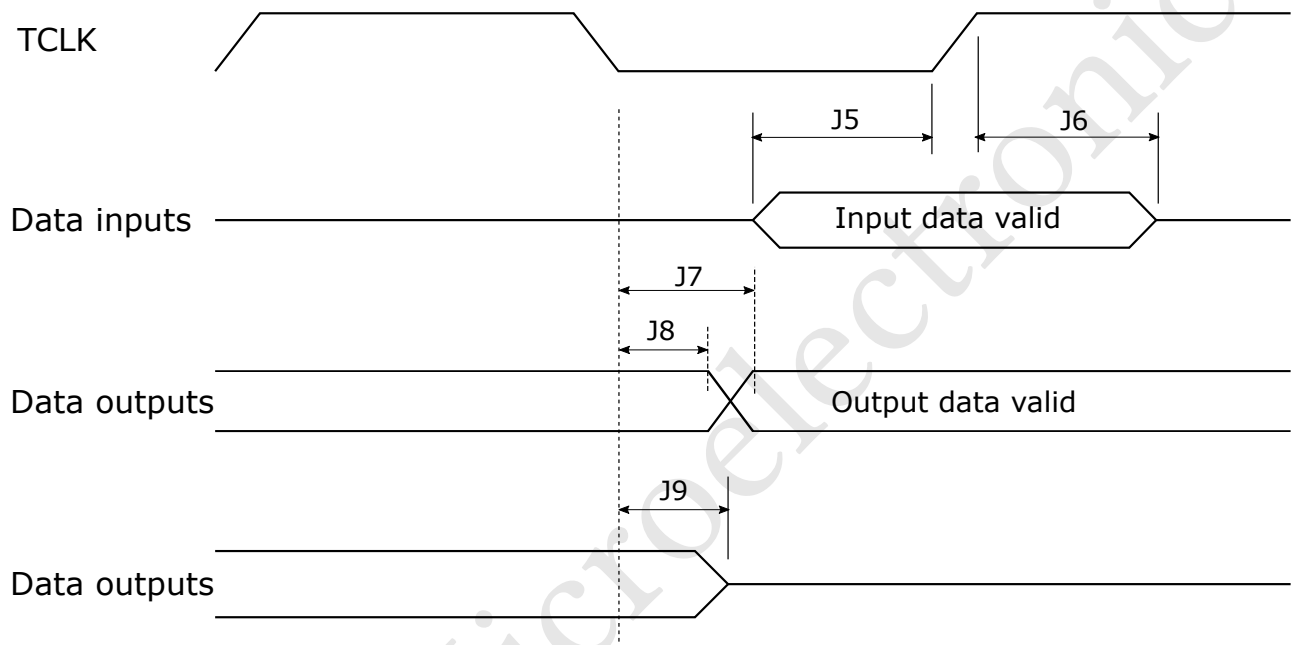


Figure 17: JTAG Data Timing

6.5 Thermal Attributes

Table 30: Thermal Characteristics

Package Family	Package Type	Thermal Resistance			Unit
		R _{JA}	R _{JC}	R _{JB}	
LQFP	LQFP64L	65	13	30	°C/W
	LQFP100L	57	13	28	°C/W
	LQFP144L	45	11	27	°C/W

NOTE: Based on environmental simulation per JEDEC standards, the PCB is a JEDEC-compliant 2S2P board. Data in this table is for reference only.

7 Pinouts

7.1 IO Signal Description

The pinouts signal description is as follows:

Table 31: Pinmux Table

144 LQFP	100 LQFP	64 LQFP	NAME	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
1	1	-	PTE_16	-	PTE_16	-	SPI2_SIN	eTMR2_CH7	eTMR4_FLT0	-	TMU_OUT7
2	2	-	PTE_15	-	PTE_15	-	SPI2_SCK	eTMR2_CH6	eTMR4_FLT1	-	TMU_OUT6
3	3	1	VDD11	VDD11	-	-	-	-	-	-	-
4	4	2	VDD25	VDD25	-	-	-	-	-	-	-
5	5	3	PTE_11	-	PTE_11	SPI2_PCS0	lpTMR0_ALT1	eTMR2_CH5	LINFlexD3_TX	ETM_TRACE_D0	TMU_OUT5
6	6	4	PTE_10	-	PTE_10	SCU_CLKOUT	SPI2_PCS1	eTMR2_CH4	LINFlexD3_RX	-	TMU_OUT4
7	7	-	PTE_13	-	PTE_13	eTMR4_CH5	SPI2_PCS2	eTMR2_FLT0	-	-	-
8	8	5	PTE_5	-	PTE_5	TCLK_IN2	eTMR2_QD_PHA	eTMR2_CH3	CAN0_TX	-	EWDG_IN
9	9	6	PTE_4	-	PTE_4	ETM_TRACE_D1	eTMR2_QD_PHB	eTMR2_CH2	CAN0_RX	-	EWDG_OUT_b
10	-	-	PTA_25	-	PTA_25	eTMR5_CH0	-	-	-	-	-
11	10	7	VDD	VDD	-	-	-	-	-	-	-
12	-	-	VSS	VSS	-	-	-	-	-	-	-
13	11	8	VDDA	VDDA	-	-	-	-	-	-	-
14	12	9	VREFH	VREFH	-	-	-	-	-	-	-
15	13	-	VREFL	VREFL	-	-	-	-	-	-	-
16	14	10	VSS	VSS	-	-	-	-	-	-	-
17	15	11	PTB_7	EXTAL	PTB_7	I2C0_SCL	-	SPI3_SCK	eTMR4_FLT3	-	TMU_OUT2
18	16	12	PTB_6	XTAL	PTB_6	I2C0_SDA	-	SPI3_SIN	eTMR4_FLT2	-	TMU_OUT1
19	-	-	PTA_26	-	PTA_26	eTMR5_CH1	SPI1_PCS0	SPI0_PCS0	-	-	-
20	17	-	PTE_14	-	PTE_14	eTMR0_FLT1	-	eTMR2_FLT1	-	-	-
21	18	13	PTE_3	-	PTE_3	eTMR0_FLT0	SPI1_SIN	eTMR2_FLT0	SPI3_SOUT	TMU_IN6	ACMP0_OUT
22	-	-	PTA_27	-	PTA_27	eTMR5_CH2	SPI1_SOUT	LINFlexD0_TX	CAN0_TX	-	-
23	19	-	PTE_12	-	PTE_12	eTMR0_FLT3	LINFlexD2_TX	eTMR5_FLT0	SPI3_PCS0	-	-
24	-	-	PTA_28	-	PTA_28	eTMR5_CH3	SPI1_SCK	LINFlexD0_RX	CAN0_RX	-	-
25	20	-	PTD_17	-	PTD_17	eTMR0_FLT2	LINFlexD2_RX	eTMR5_FLT1	-	-	-
26	-	-	PTA_29	-	PTA_29	eTMR5_CH4	-	LINFlexD2_TX	SPI1_SIN	-	-
27	-	-	PTA_30	-	PTA_30	eTMR5_CH5	LINFlexD2_RX	SPI0_SOUT	-	-	-
28	21	14	PTD_16	EXTAL32	PTD_16	eTMR0_CH1	CAN4_TX	SPI0_SIN	ACMP0_ACTIVE	ETM_TRACE_D2	ETM_TRACE_CLKOUT
29	22	15	PTD_15	XTAL32	PTD_15	eTMR0_CH0	CAN4_RX	SPI0_SCK	-	ETM_TRACE_D3	-
30	23	16	PTE_9	-	PTE_9	eTMR0_CH7	SPI1_SCK	I2C2_SDA	-	-	-
31	-	-	VSS	VSS	-	-	-	-	-	-	-
32	-	-	VDD	VDD	-	-	-	-	-	-	-
33	-	-	PTA_31	-	PTA_31	eTMR5_CH6	-	SPI0_PCS1	-	-	-
34	24	-	PTD_14	-	PTD_14	eTMR2_CH5	LINFlexD1_TX	-	SPI5_PCS3	-	SCU_CLKOUT
35	25	-	PTD_13	-	PTD_13	eTMR2_CH4	LINFlexD1_RX	-	SPI5_PCS2	-	RTC_CLKOUT
36	-	-	PTB_18	ADC0_SE16	PTB_18	eTMR5_CH7	-	SPI1_PCS1	-	-	-
37	-	-	PTB_20	ADC0_SE17	PTB_20	LINFlexD3_TX	-	-	I2C1_SDA	-	-
38	-	-	PTB_21	ADC0_SE18	PTB_21	LINFlexD3_RX	-	-	I2C1_SCL	-	-
39	26	17	PTE_8	ACMP0_IN3	PTE_8	eTMR0_CH6	-	I2C2_SCL	SPI3_PCS1	-	-
40	27	18	PTB_5	-	PTB_5	eTMR0_CH5	SPI0_PCS1	SPI0_PCS0	SCU_CLKOUT	TMU_IN0	-
41	28	19	PTB_4	-	PTB_4	eTMR0_CH4	SPI0_SOUT	-	-	TMU_IN1	-
42	29	20	PTC_3	ADC0_SE11 ACMP0_IN4	PTC_3	eTMR0_CH3	CAN0_TX	LINFlexD0_TX	SPI4_PCS0	-	-
43	30	21	PTC_2	ADC0_SE10 ACMP0_IN5	PTC_2	eTMR0_CH2	CAN0_RX	LINFlexD0_RX	SPI4_SCK	ETM_TRACE_CLKOUT	-
44	31	22	PTD_7	ACMP0_IN6	PTD_7	LINFlexD2_TX	eTMR0_CH3	eTMR2_FLT3	SPI4_SIN	ETM_TRACE_D0	-

144 LQFP	100 LQFP	64 LQFP	NAME	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
45	32	23	PTD_6	ACMP0_IN7	PTD_6	LINFlexD2_RX	eTMR0_CH2	eTMR2_FLT2	SPI4_SOUT	-	-
46	33	24	PTD_5	-	PTD_5	eTMR2_CH3	lpTMR0_ALT2	eTMR2_FLT1	SPI4_PCS1	TMU_IN7	-
47	34	-	PTD_12	-	PTD_12	eTMR2_CH2	-	ETM_TRACE_D1	SPI5_SIN	-	-
48	35	-	PTD_11	-	PTD_11	eTMR2_CH1	eTMR2_QD_PHA	ETM_TRACE_D2	SPI5_SOUT	-	-
49	36	-	PTD_10	-	PTD_10	eTMR2_CH0	eTMR2_QD_PHB	ETM_TRACE_D3	SPI5_SCK	SCU_CLKOUT	-
50	37	-	VSS	VSS	-	-	-	-	-	-	-
51	38	-	VDD	VDD	-	-	-	-	-	-	-
52	39	25	PTC_1	ADC0_SE9	PTC_1	eTMR0_CH1	SPI2_SOUT	CAN3_TX	-	eTMR1_CH7	-
53	40	26	PTC_0	ADC0_SE8	PTC_0	eTMR0_CH0	SPI2_SIN	CAN3_RX	-	eTMR1_CH6	-
54	41	-	PTD_9	-	PTD_9	LINFlexD4_TX	-	eTMR2_FLT3	-	eTMR1_CH5	-
55	42	-	PTD_8	-	PTD_8	LINFlexD4_RX	-	eTMR2_FLT2	-	eTMR1_CH4	-
56	43	27	PTC_17	ADC0_SE15	PTC_17	eTMR1_FLT3	CAN2_TX	SPI4_PCS0	eTMR2_CH1	-	-
57	44	28	PTC_16	ADC0_SE14	PTC_16	eTMR1_FLT2	CAN2_RX	SPI4_SCK	eTMR2_CH0	-	-
58	-	-	PTB_22	ADC0_SE19	PTB_22	-	-	-	LINFlexD1_TX	-	-
59	45	29	PTC_15	ADC0_SE13	PTC_15	eTMR1_CH3	SPI2_SCK	SPI4_SIN	LINFlexD4_TX	TMU_IN8	-
60	-	-	PTB_23	ADC0_SE20	PTB_23	-	LINFlexD1_RX	-	-	-	-
61	46	30	PTC_14	ADC0_SE12	PTC_14	eTMR1_CH2	SPI2_PCS0	SPI4_SOUT	LINFlexD4_RX	TMU_IN9	-
62	-	-	PTB_25	ADC0_SE21	PTB_25	-	-	SPI4_PCS1	SPI2_PCS0	-	-
63	47	31	PTB_3	ADC0_SE7	PTB_3	eTMR1_CH1	SPI0_SIN	eTMR1_QD_PHA	-	TMU_IN2	-
64	-	-	PTB_27	ADC0_SE22	PTB_27	eTMR5_FLT2	-	-	SPI2_SOUT	-	-
65	-	-	PTB_28	ADC0_SE23	PTB_28	eTMR5_FLT3	-	-	SPI2_SIN	-	-
66	-	-	VSS	VSS	-	-	-	-	-	-	-
67	-	-	VDD	VDD	-	-	-	-	-	-	-
68	48	32	PTB_2	ADC0_SE6	PTB_2	eTMR1_CH0	SPI0_SCK	eTMR1_QD_PHB	-	TMU_IN3	-
69	-	-	PTB_29	-	PTB_29	-	-	-	SPI2_SCK	-	-
70	49	-	PTC_13	-	PTC_13	eTMR3_CH7	eTMR2_CH7	-	-	-	-
71	50	-	PTC_12	-	PTC_12	eTMR3_CH6	eTMR2_CH6	-	-	-	-
72	-	-	PTC_19	-	PTC_19	-	-	-	SPI2_PCS1	-	-
73	-	-	PTC_23	-	PTC_23	SPI0_SCK	-	-	-	-	-
74	51	-	PTC_11	-	PTC_11	eTMR3_CH5	eTMR4_CH2	CAN5_TX	-	TMU_IN10	-
75	52	-	PTC_10	-	PTC_10	eTMR3_CH4	-	CAN5_RX	-	TMU_IN11	-
76	-	-	PTC_27	-	PTC_27	eTMR4_CH4	-	-	-	-	-
77	53	33	PTB_1	ADC0_SE5	PTB_1	LINFlexD0_TX	SPI0_SOUT	TCLK_IN0	CAN0_TX	eTMR4_CH5	-
78	54	34	PTB_0	ADC0_SE4	PTB_0	LINFlexD0_RX	SPI0_PCS0	lpTMR0_ALT3	CAN0_RX	eTMR4_CH6	-
79	-	-	PTC_28	-	PTC_28	eTMR4_CH7	-	-	-	-	-
80	55	35	PTC_9	-	PTC_9	LINFlexD1_TX	eTMR1_FLT1	eTMR5_CH0	CAN4_TX	SPI5_PCS1	-
81	56	36	PTC_8	-	PTC_8	LINFlexD1_RX	eTMR1_FLT0	eTMR5_CH1	CAN4_RX	SPI5_PCS0	-
82	-	-	PTC_29	-	PTC_29	eTMR5_CH2	-	-	-	-	-
83	57	37	PTA_7	ADC0_SE3	PTA_7	eTMR0_FLT2	eTMR5_CH3	RTC_CLKIN	I2C2_SCL	SPI5_SCK	-
84	-	-	PTC_30	-	PTC_30	eTMR5_CH4	-	-	-	-	-
85	58	38	PTA_6	ADC0_SE2	PTA_6	eTMR0_FLT1	SPI1_PCS1	eTMR5_CH5	I2C2_SDA	SPI5_SIN	-
86	-	-	PTC_31	-	PTC_31	eTMR5_CH6	-	-	-	-	-
87	59	39	PTE_7	-	PTE_7	eTMR0_CH7	eTMR3_FLT0	-	-	SPI5_SOUT	-
88	-	-	PTD_18	ADC1_SE16	PTD_18	eTMR5_CH7	-	CAN5_TX	-	-	-
89	-	-	PTD_19	ADC1_SE17	PTD_19	-	-	CAN5_RX	-	-	-
90	60	40	VSS	VSS	-	-	-	-	-	-	-
91	61	41	VDD	VDD	-	-	-	-	-	-	-
92	62	-	PTA_17	-	PTA_17	eTMR0_CH6	eTMR3_FLT0	EWDG_OUT_b	eTMR5_FLT0	-	-
93	63	-	PTB_17	-	PTB_17	eTMR0_CH5	SPI1_PCS3	eTMR5_FLT1	-	-	-
94	64	-	PTB_16	ADC1_SE15	PTB_16	eTMR0_CH4	SPI1_SOUT	-	-	-	-
95	65	-	PTB_15	ADC1_SE14	PTB_15	eTMR0_CH3	SPI1_SIN	-	-	-	-
96	66	-	PTB_14	ADC1_SE9	PTB_14	eTMR0_CH2	SPI1_SCK	-	-	-	-

144 LQFP	100 LQFP	64 LQFP	NAME	ALT0	ALT1	ALT2	ALT3	ALT4	ALT5	ALT6	ALT7
97	67	42	PTB_13	ADC1_SE8	PTB_13	eTMR0_CH1	eTMR3_FLT1	CAN2_TX	-	-	-
98	68	43	PTB_12	ADC1_SE7	PTB_12	eTMR0_CH0	eTMR3_FLT2	CAN2_RX	-	-	-
99	-	-	PTD_22	ADC1_SE18	PTD_22	eTMR4_FLT2	-	-	-	-	-
100	69	44	PTD_4	ADC1_SE6	PTD_4	eTMR0_FLT3	eTMR3_FLT3	-	-	SPI5_PCS2	-
101	70	45	PTD_3	ADC1_SE3	PTD_3	eTMR3_CH5	SPI1_PCS0	I2C1_SCL	CAN5_TX	TMU_IN4	NMI_b
102	71	46	PTD_2	ADC1_SE2	PTD_2	eTMR3_CH4	SPI1_SOUT	I2C1_SDA	CAN5_RX	TMU_IN5	-
103	-	-	PTD_23	ADC1_SE19	PTD_23	eTMR4_FLT3	-	-	-	-	-
104	72	47	PTA_3	ADC1_SE1	PTA_3	eTMR3_CH1	I2C0_SCL	EWDG_IN	-	LINFLEXD0_TX	-
105	73	48	PTA_2	ADC1_SE0	PTA_2	eTMR3_CH0	I2C0_SDA	EWDG_OUT_b	-	LINFLEXD0_RX	-
106	-	-	PTD_24	ADC1_SE20	PTD_24	-	-	-	-	-	-
107	74	-	PTB_11	-	PTB_11	eTMR3_CH3	LINFLEXD5_TX	-	-	-	-
108	75	-	PTB_10	-	PTB_10	eTMR3_CH2	LINFLEXD5_RX	-	-	-	-
109	76	-	PTB_9	-	PTB_9	eTMR3_CH1	-	-	-	-	-
110	-	-	PTD_27	ADC1_SE21	PTD_27	eTMR5_FLT2	-	-	-	-	-
111	77	-	PTB_8	-	PTB_8	eTMR3_CH0	-	-	-	-	-
112	-	-	PTD_28	ADC1_SE22	PTD_28	eTMR5_FLT3	-	-	-	-	-
113	78	49	PTA_1	ADC0_SE1 ACMP0_IN1	PTA_1	eTMR1_CH1	LINFLEXD5_TX	-	eTMR1_QD_PHA	-	TMU_OUT0
114	-	-	PTD_29	ADC1_SE23	PTD_29	-	-	-	-	-	-
115	79	50	PTA_0	ADC0_SE0 ACMP0_IN0	PTA_0	eTMR2_CH1	LINFLEXD5_RX	-	eTMR2_QD_PHA	-	TMU_OUT3
116	-	-	PTD_30	-	PTD_30	-	-	-	-	-	-
117	80	51	PTC_7	ADC1_SE5	PTC_7	LINFLEXD1_TX	CAN1_TX	eTMR3_CH3	-	eTMR1_QD_PHA	-
118	81	52	PTC_6	ADC1_SE4	PTC_6	LINFLEXD1_RX	CAN1_RX	eTMR3_CH2	-	eTMR1_QD_PHB	-
119	82	-	PTA_16	ADC1_SE13	PTA_16	eTMR1_CH3	SPI1_PCS2	-	-	-	-
120	83	-	PTA_15	ADC1_SE12	PTA_15	eTMR1_CH2	SPI0_PCS3	SPI2_PCS3	-	-	-
121	84	53	PTE_6	ADC1_SE11	PTE_6	SPI0_PCS2	-	eTMR3_CH7	-	ETM_TRACE_D2	ETM_TRACE_CLKOUT
122	85	54	PTE_2	ADC1_SE10	PTE_2	SPI0_SOUT	lpTMR0_ALT3	eTMR3_CH6	-	ETM_TRACE_D3	-
123	86	-	VSS	VSS	-	-	-	-	-	-	-
124	87	-	VDD	VDD	-	-	-	-	-	-	-
125	-	-	PTE_19	-	PTE_19	-	-	-	-	-	-
126	-	-	PTE_20	-	PTE_20	eTMR4_CH0	-	-	-	-	-
127	88	-	PTA_14	-	PTA_14	eTMR0_FLT0	eTMR3_FLT1	EWDG_IN	-	eTMR1_FLT0	-
128	-	-	PTE_21	-	PTE_21	eTMR4_CH1	-	-	-	-	-
129	-	-	PTE_22	-	PTE_22	eTMR4_CH2	-	-	-	-	-
130	89	55	PTA_13	-	PTA_13	eTMR1_CH7	CAN1_TX	SPI3_PCS0	-	eTMR2_QD_PHA	-
131	-	-	PTE_23	-	PTE_23	eTMR4_CH3	-	-	-	-	-
132	-	-	PTE_24	-	PTE_24	eTMR4_CH4	CAN2_TX	-	-	-	-
133	-	-	PTE_25	-	PTE_25	eTMR4_CH5	CAN2_RX	-	-	-	-
134	90	56	PTA_12	-	PTA_12	eTMR1_CH6	CAN1_RX	SPI3_SCK	-	eTMR2_QD_PHB	-
135	91	57	PTA_11	-	PTA_11	eTMR1_CH5	-	SPI3_SIN	ACMP0_ACTIVE	-	-
136	92	58	PTA_10	-	PTA_10	eTMR1_CH4	-	SPI3_SOUT	-	-	JTAG_TDO_SWD_SWO
137	93	59	PTE_1	-	PTE_1	SPI0_SIN	-	-	SPI1_PCS0	eTMR1_FLT1	-
138	94	60	PTE_0	-	PTE_0	SPI0_SCK	TCLK_IN1	-	SPI1_SOUT	eTMR1_FLT2	-
139	95	61	PTC_5	-	PTC_5	eTMR2_CH0	RTC_CLKOUT	SPI3_PCS1	-	eTMR2_QD_PHB	JTAG_TDI
140	96	62	PTC_4	ACMP0_IN2	PTC_4	eTMR1_CH0	RTC_CLKOUT	-	EWDG_IN	eTMR1_QD_PHB	JTAG_TCK_SWD_CLK
141	97	63	PTA_5	-	PTA_5	CAN3_TX	TCLK_IN1	-	-	-	RESET_b
142	98	64	PTA_4	-	PTA_4	CAN3_RX	-	ACMP0_OUT	EWDG_OUT_b	-	JTAG_TMS_SWD_IO
143	99	-	PTA_9	-	PTA_9	LINFLEXD2_TX	SPI2_PCS0	-	eTMR3_FLT2	eTMR1_FLT3	eTMR4_FLT0
144	100	-	PTA_8	-	PTA_8	LINFLEXD2_RX	SPI2_SOUT	-	eTMR3_FLT3	eTMR4_FLT1	-

7.2 Packages

The information of package pinouts is as follows:

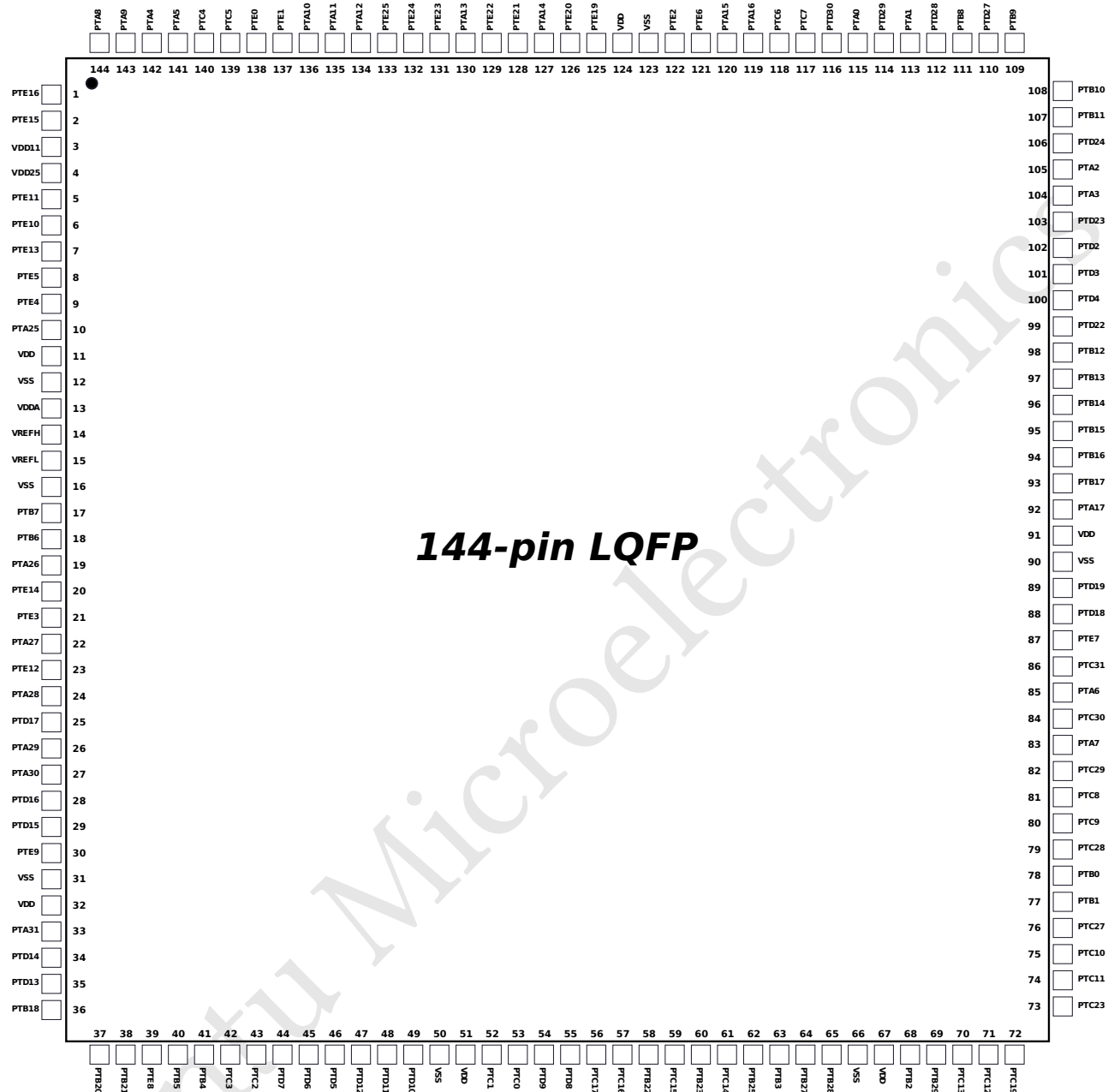


Figure 18: 144-pin LQFP Package

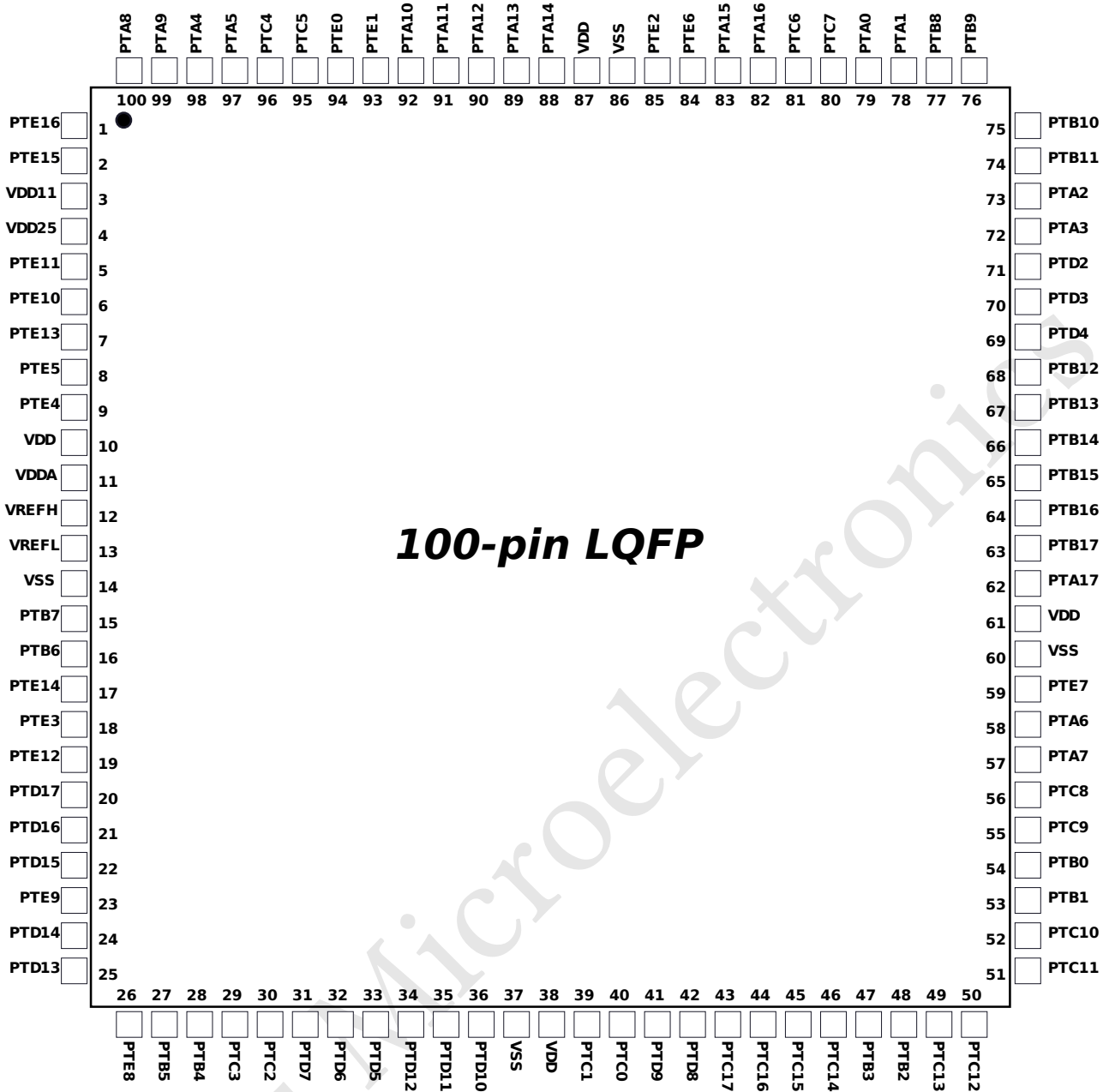


Figure 19: 100-pin LQFP Package

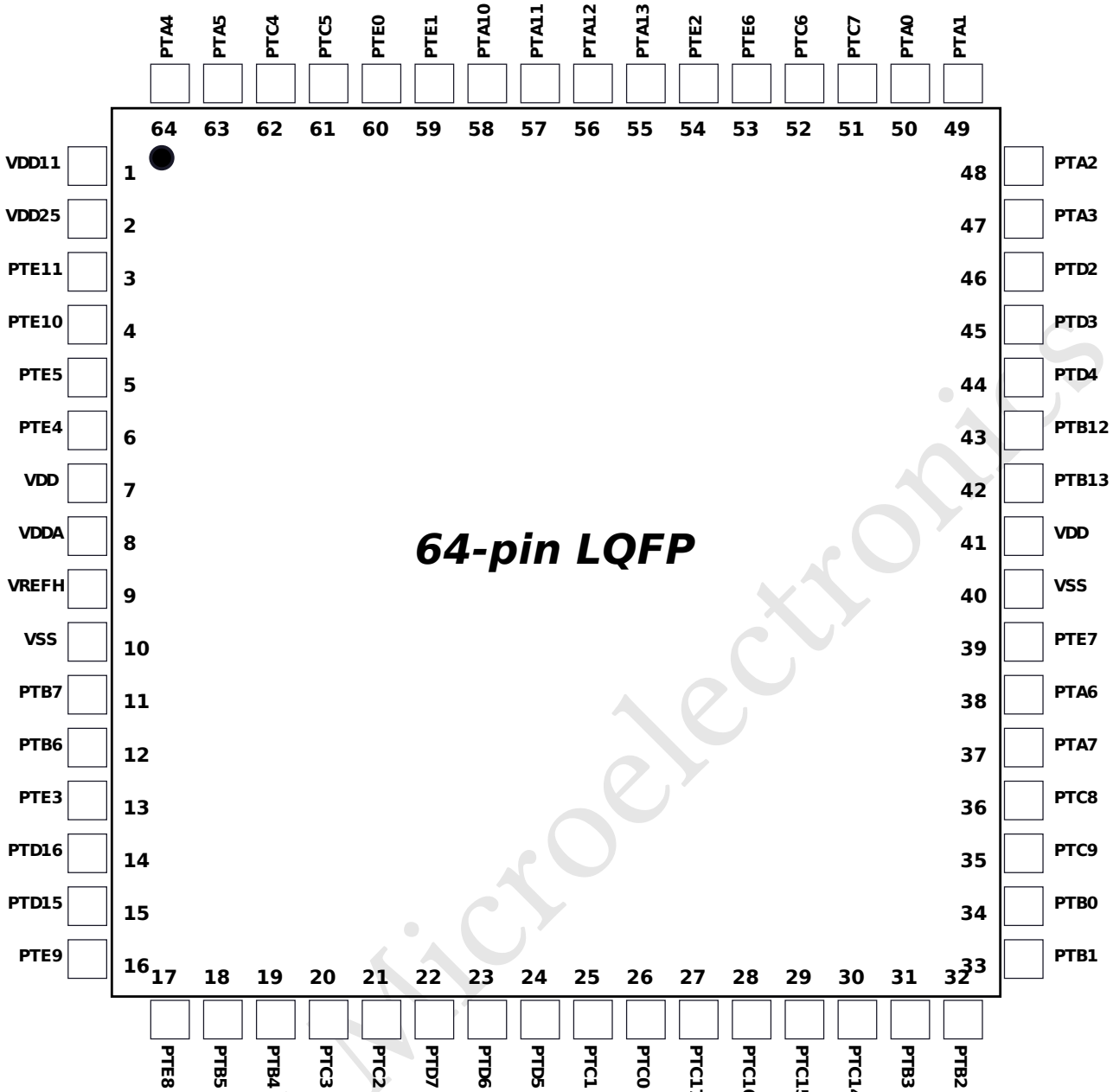


Figure 20: 64-pin LQFP Package

NOTE: The chip mark will not contain packing information(T/R)

7.3 Dimensions

Package dimensions are as follows:

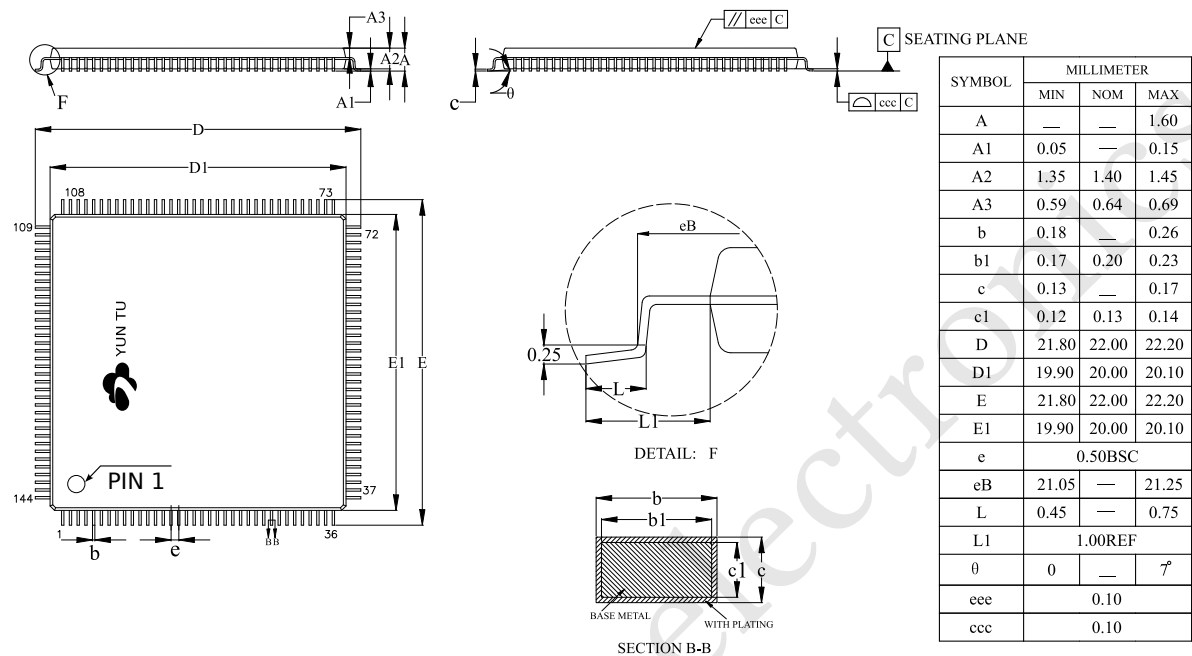


Figure 21: 144-pin LQFP

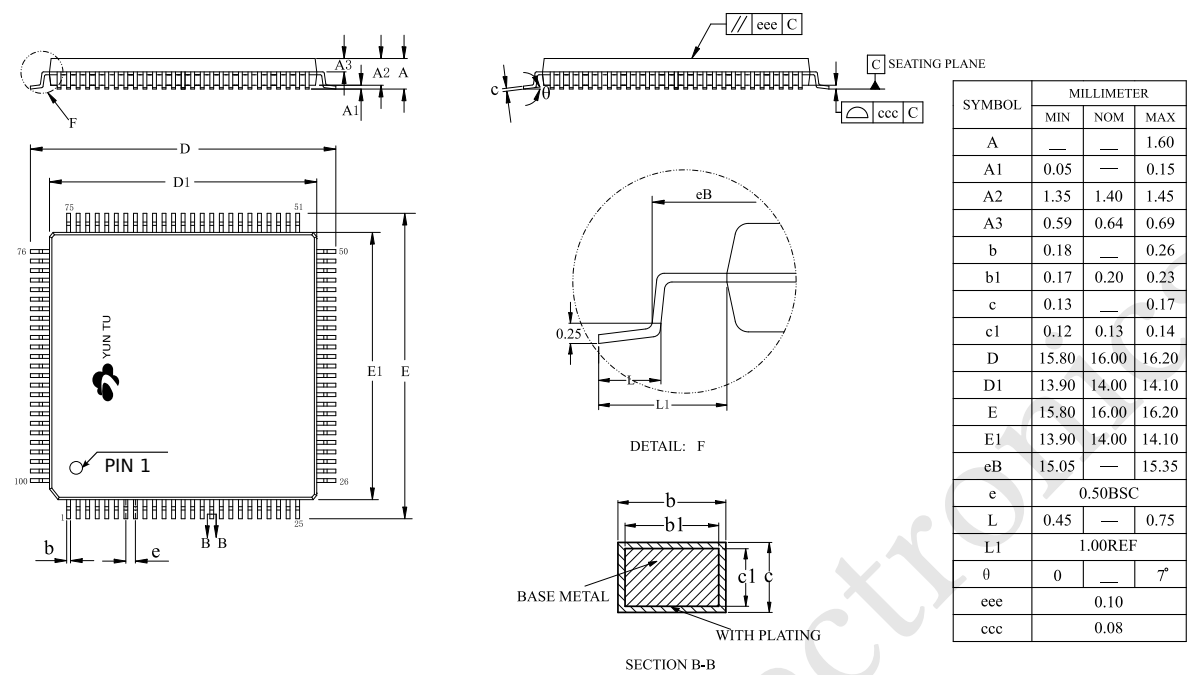


Figure 22: 100-pin LQFP

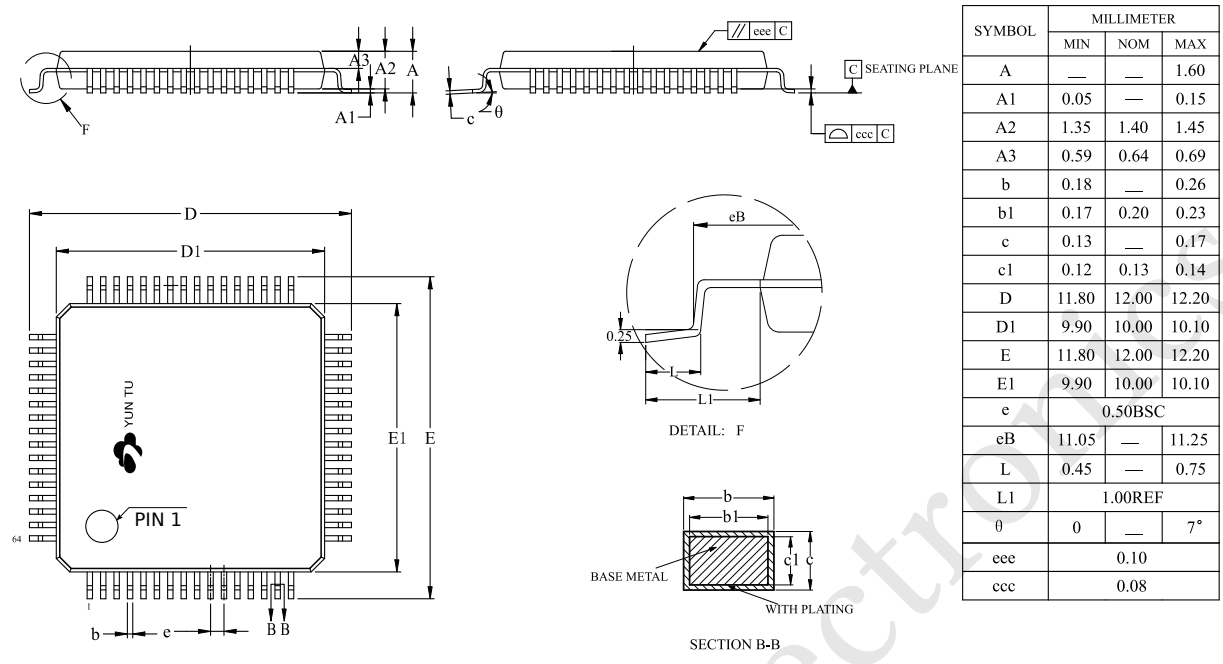


Figure 23: 64-pin LQFP

7.4 Reflow Profile Guideline

Reflow Condition:

- can guarantee 3X IR reflow base on the Reflow profile(Figure 5-1) guideline in IPC/JEDEC J-STD-020E;
- Preheat/Soak: Pb-Free Assembly for 150°C~200°C for 60~120s;
- Average ramp-up rate(Ts to peak):3°C/second max.;
- Liquidous temperature maintained above Pb-Free 217°C for 60-150s;
- Time (tp)* within 5°C of the specified classification temperature Pb-Free 30s ;
- Note :

Reflow profiles in this document are for classification/preconditioning and are not meant to specify board assembly profiles. Actual board assembly profiles should be developed based on specific process needs and board designs and should not exceed the parameters in this table. For example, if Tc is 260°C and time Tp is 30 seconds, this means the following for the supplier and the user:
For a supplier: The peak temperature must be at least 260°C. The time above 255°C must be at least 30 seconds.
For a user: The peak temperature must not exceed 260°C. The time above 255°C must not exceed 30 seconds.

Table 4-2 Pb-Free Process – Classification Temperatures (T_c)

Package Thickness	Volume mm ³ <350	Volume mm ³ 350 - 2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm - 2.5 mm	260 °C	250 °C	245 °C
>2.5 mm	250 °C	245 °C	245 °C

Table 5-2 Classification Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat/Soak		
Temperature Min (T _{smin})	100 °C	150 °C
Temperature Max (T _{smax})	150 °C	200 °C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds	60-120 seconds
Ramp-up rate (T _L to T _p)	3 °C/second max.	3 °C/second max.
Liquidous temperature (T _L)	183 °C	217 °C
Time (t _L) maintained above T _L	60-150 seconds	60-150 seconds
Peak package body temperature (T _p)	For users T _p must not exceed the Classification temp in Table 4-1. For suppliers T _p must equal or exceed the Classification temp in Table 4-1.	For users T _p must not exceed the Classification temp in Table 4-2. For suppliers T _p must equal or exceed the Classification temp in Table 4-2.
Time (t _p)* within 5 °C of the specified classification temperature (T _c), see Figure 5-1.	20* seconds	30* seconds
Ramp-down rate (T _p to T _L)	6 °C/second max.	6 °C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

* Tolerance for peak profile temperature (T_p) is defined as a supplier minimum and a user maximum.

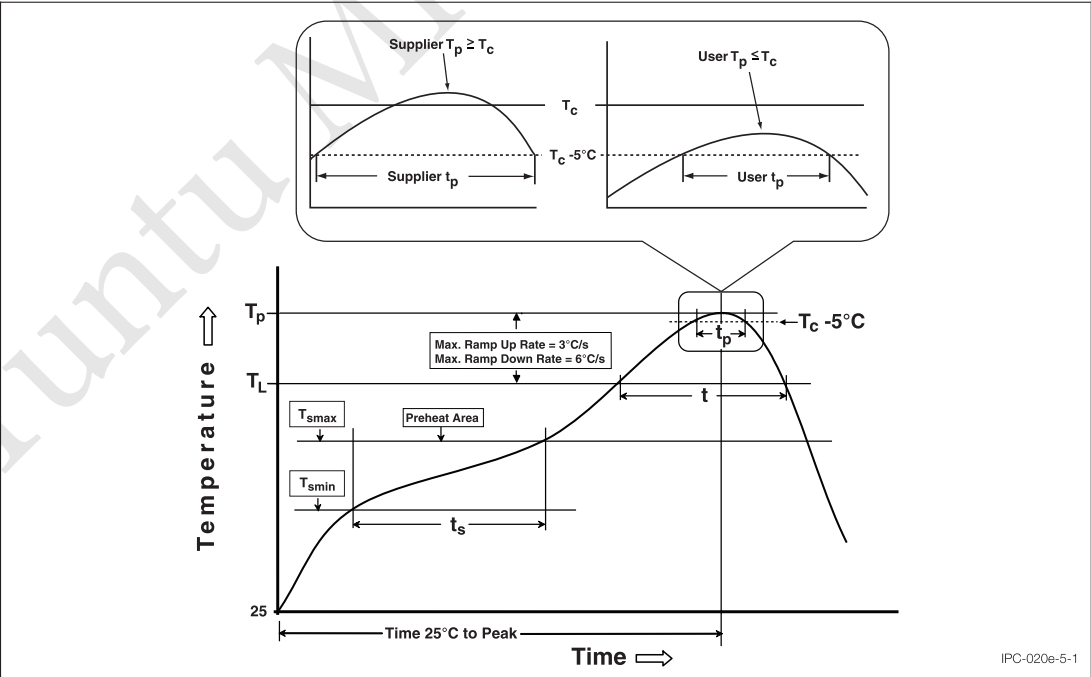


Figure 5-1 Classification Profile (Not to scale)

Figure 24: Reflow Profile Guideline

Revision History

The following table provides a revision history for this document.

Rev.No.	Date	Substantive Change(s)
1.0	2022/4/28	Initial version
1.1	2022/5/06	Updated FXOSC, SXOSC and PLL parameters
1.2	2022/5/21	Updated Pinout decoupling Removed internal ADC channel in 144pin
1.3	2022/8/15	Fixed E1 of 100 pin package
1.4	2023/3/13	Updated the contents in the chapter of "Features Summary" Updated the figure of "YTM32B1ME0x Block Diagram" Added the new chapter of "Features" Corrected the symbol of "Thermal Operating Characteristics" Corrected V_{LAT} to I_{LAT} in "ESD Handling Ratings" Updated the description of "Power Consumption" Corrected 32KHz to 32.768KHz in "SXOSC(32.768 KHz) Characteristics" Corrected the value in "PLL Characteristics" Removed the parameters of DNL and INL in "ADC Characteristics" Added the new section of "Thermal Attributes" Corrected the sign of ADC channel in "Pinmux Table"
1.5	2023/4/28	Added the information on ASIL B in "Features Summary" and "Overview" Added the support for ISELED in "Ordering Information" Updated the contents in "Absolute Maximum Ratings" Updated the contents in "Voltage and Current Operating Requirements" Updated the contents of "DC Electrical Specifications at 3.3V" Updated the contents of "DC Electrical Specifications at 5.0V" Updated the type values in "Power Mode Transition Operating Behaviors" Updated the contents in "Power Consumption" Corrected the value of Max. to Typ. in "Device Clock Specifications" Updated the contents of "FXOSC(4-40MHz) Characteristics" Updated the contents of "SXOSC(32.768KHz) Characteristics" Added one note in "ADC Characteristics" Updated the contents of "ACMP Characteristics" Removed the unnecessary contents in "Thermal Attributes"
1.6	2023/6/21	Added the coplanarity specifications of product in the section of "Dimensions" Added the location information of PIN 1 in the section of "Dimensions"
1.7	2023/7/28	Updated the TBD data of I_{OI} in "DC Electrical Specifications at 5.0V" Updated the heading of 6.2.5 to "Power and Ground Pins" Corrected the description and value in "Power Consumption" Updated the TBD data, the table and the figure of ADC Circuit in "ADC Characteristics" Updated the TBD data "ACMP Characteristics"
1.8	2024/10/24	Added high drive pin information, corrected the temperature and I_{IN} value in "DC Electrical Specifications at 3.3V" Added high drive pin information, corrected the temperature and I_{IN} value in "DC Electrical Specifications at 5.0V" Added the capacitance information of C_{DEC1} in "Power and Ground Pins" Updated the ACC_{firc} value in "FIRC(96 MHz) Characteristics" Updated the ACC_{sirc} value in "SIRC(12 MHz) Characteristics" Updated all package dimensions to latest version in "Dimensions"
1.9	2025/1/17	Added Min and Max value in subsection of "Moisture Handling Ratings" Added Min and Max value in subsection of "Absolute Maximum Ratings" Added Min and Max value in subsection of "Voltage and Current Operating Requirements" Added Min and Max value in subsection of "DC Electrical Specifications at 3.3V" Added Min and Max value in subsection of "DC Electrical Specifications at 5.0V" Added Min and Max value in subsection of "Power and Ground Pins" Updated the data of V_{POR} in subsection of "POR,LVR and LVD Operating Requirements" Added Min and Max value in subsection of "Power Consumption" Added the subsubsection of "MCU Power Supply Ramp Rate" Added the whole subsection of "Power Supply Fluctuation Requirements" Added Min and Max value in subsection of "FXOSC(4-40MHz) Characteristics" Added Min and Max value in subsection of "SXOSC(32.768KHz) Characteristics" Updated Max value in subsection of "PLL Characteristics" Added Min and Max value in subsection of "FIRC(48MHz) Characteristics" Added Min and Max value in subsection of "SIRC(2MHz) Characteristics" Added Min and Max value in subsection of "ADC Characteristics" Added Min and Max value in subsection of "ACMP Characteristics" Updated Max value in subsubsection of "Flash Timing Specifications-Commands"
2.0	2025/6/6	Corrected the max value of V_{IL} in subsection of "FXOSC(4-40MHz) Characteristics" Updated the max value of F_{VCO} and F_{OUT} in subsection of "PLL Characteristics" Added the whole subsection of "SPI Characteristics" Added the value of R_{JC} , R_{JB} and note in the section of "Thermal Attributes"

Rev.No.	Date	Substantive Change(s)
2.1	2025/8/15	Added the value of T_{clock} in subsection of "PLL Characteristics" Corrected the value of F_{ADC} in subsection of "ADC Characteristics" Corrected the Min value of V_{IN} in subsection of "ACMP Characteristics" Corrected the value of f_{op} and t_{SCK} in subsection of "SPI Characteristics"
2.2	2025/12/18	Added the part number about cost optimization in chapter of "Ordering Information" Added the chip storage conditions in subsection of "Moisture Handling Ratings" Updated the information of g_m and V_{PP} in subsection of "FXOSC(4-40MHz) Characteristics" Updated the information of g_m in subsection of "SXOSC(32.768KHz) Characteristics" Added the clock source information in subsection of "FIRC(96MHz) Characteristics" Added the clock source information in subsection of "SIRC(12MHz) Characteristics" Updated the table in subsection of "ADC Characteristics" Added the section of "Reflow Profile Guideline" in chapter of "Pinouts"

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